

Preliminary Data Sheet

MU9C4480A/L LANCAMs®

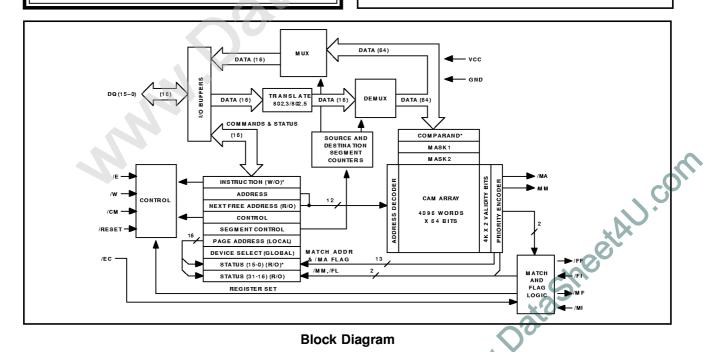
APPLICATION BENEFITS

The 4096 x 64 bit LANCAM facilitates numerous operations:

- New speed grade allows processing of both DA and SA within 560 ns, equivalent to 111, 10 Base-T or 11, 100 Base-T Ethernet ports
- > Higher density enables longer station lists
- Expanded powerful instruction set for any list processing needs
- Fully Compatible with all MUSIC LANCAM Series, cascadable to any practical length without performance penalties
- Full CAM features allow all operations mask, on a bit per bit basis

DISTINCTIVE CHARACTERISTICS

- 4096 x 64-bit CMOS content-addressable memory (CAM)
- 16-bit I/O
- Fast 70 ns compare speed
- Dual configuration register set for rapid context switching
- > 16-bit CAM/RAM segments with MUSIC's patented partitioning
- /MA and /MM output flags to enable faster system performance
- Readable Device ID
- Selectable faster operating mode with no wait states after a no-match
- > 44-pin PLCC package
- > 5 volt (4480A) or 3.3 volt (4480L) operation
- Industrial temperature grade available



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GENERAL DESCRIPTION

The MU9C4480A and MU9C4480L LANCAMs are 4096 x 64-bit content-addressable memories (CAMs), with 16-bit wide interfaces. They are pin compatible with all devices in the MUSIC LANCAM family.

Content-addressable memories, also known as associative memories, operate in the converse way to random access memories (RAM). In RAM, the input to the device is an address and the output is the data stored at that address. In CAM, the input is a data sample and the output is a flag to indicate a match and the address of the matching data. As a result, CAM searches large databases for matching data in a short, constant time period, no matter how many entries are in the database. The ability to search data words up to 64 bits wide allows large address spaces to be searched rapidly and efficiently. A patented architecture links each CAM entry to associated data and makes this data available for use after a successful compare operation.

The MUSIC LANCAMs are ideal for address filtering and translation applications in LAN switches and routers. The LANCAMs are also well suited to encryption, database accelerators, and image processing.

OPERATIONAL OVERVIEW

To use the LANCAM, the user loads the data into the Comparand register, which is automatically compared to all valid CAM locations. The device then indicates whether or not one or more of the valid CAM locations contains data that matches the target data. The status of each CAM location is determined by two validity bits at each memory location. The two bits are encoded to render four validity conditions: Valid, Skip, Empty, and Random Access, as shown in Table 1. The memory can be partitioned into CAM and associated RAM segments on 16-bit boundaries, but by using either of the two available mask registers, the CAM/RAM partitioning can be set at any arbitrary size between zero and 64 bits.

The LANCAM's internal data path is 64 bits wide for rapid internal comparison and data movement. Vertical cascading of additional LANCAMs in a daisy chain fashion extends the CAM memory depth for large databases. Cascading requires no external logic. Loading data to the Control, Comparand, and mask registers automatically triggers a compare. Compares may also be initiated by a command to

Skip Bit	Empty Bit	Entry Type		
0	0	Valid		
0	1	Empty		
1	0	Skip		
1	1	RAM		

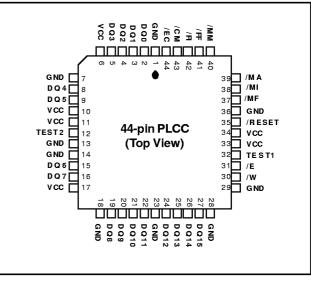
Table 1: Entry Types vs. Validity Bits

/W	/CM	Сусіе Туре
LOW	LOW	Command Write Cycle
LOW	HIGH	Data Write Cycle
HIGH	LOW	Command Read Cycle
HIGH	HIGH	Data Read Cycle
	Table 2. I	O Cycles

ole 2: I/O Cycles

the device. Associated RAM data is available immediately after a successful compare operation. The Status register reports the results of compares including all flags and addresses. Two mask registers are available and can be used in two different ways: to mask comparisons or to mask data writes. The random access validity type allows additional masks to be stored in the CAM array where they may be retrieved rapidly.

The device is controlled by a simple four-wire control interface and commands loaded into the Instruction Decoder. A powerful instruction set increases the control flexibility and minimizes software overhead. Additionally, dedicated pins for match and multiple-match flags enhance performance when the device is controlled by a state machine. These and other features make the LANCAM a powerful associative memory that drastically reduces search delays.



PINOUT DIAGRAM

PIN DESCRIPTIONS

All signals are implemented in CMOS technology with TTL levels. Signal names that start with a slash ("/") are active LOW. Inputs should never be left floating. The CAM architecture draws large currents during compare operations, mandating the use of good layout and bypassing techniques. Refer to the Electrical Characteristics section for more information.

/E (Chip Enable, Input, TTL)

The /E input enables the device while LOW. The falling edge registers the control signals /W, /CM, and /EC. The rising edge locks the daisy chain, turns off the DQ pins, and clocks the Destination and Source Segment counters. The four cycle types enabled by /E are shown in Table 2.

/W (Write Enable, Input, TTL)

The /W input selects the direction of data flow during a device cycle. /W LOW selects a Write cycle and /W HIGH selects a Read cycle.

/CM (Data/Command Select, Input, TTL)

The /CM input selects whether the input signals on DQ15–0 are data or commands. /CM LOW selects Command cycles and /CM HIGH selects Data cycles.

/EC (Enable Daisy Chain, Input, TTL)

The /EC signal performs two functions. The /EC input enables the /MF output to show the results of a comparison, as shown in Figure 6 on page 14. If /EC is LOW at the falling edge of /E in a given cycle, the /MF output is enabled. Otherwise, the /MF output is held HIGH. The /EC signal also enables the /MF-/MI daisy chain, which serves to select the device with the highest-priority match in a string of LANCAMs. Tables 5a and 5b on page 11 explain the effect of the /EC signal on a device with or without a match in both Standard and Enhanced modes. /EC must be HIGH during initialization.

DQ15-0 (Data Bus, I/O, TTL)

The DQ15–0 lines convey data, commands, and status to and from the LANCAM. The direction and nature of the information that flows to or from the device are controlled by /W and /CM. When /E is HIGH, DQ15–0 go to Hi-Z.

/MF (Match Flag, Output, TTL)

The /MF output goes LOW when one or more valid matches occur during a compare cycle. /MF becomes valid after /E goes HIGH on the cycle that enables the daisy chain (on the first cycle that /EC is registered LOW by the previous falling edge of /E; see Figure 6 on page 14). In a daisy chain, valid match(es) in higher priority devices are passed from the /MI input to /MF. If the daisy chain is enabled but the match flag is disabled in the Control register, the /MF output only depends on the /MI input of the device (/MF=/MI). /MF is HIGH if there is no match or when the daisy chain is disabled (/E goes HIGH when /EC was HIGH on the previous falling edge of /E). The System Match flag is the /MF pin of the last device in the

daisy chain. /MF will be reset when the active configuration register set is changed.

/MI (Match Input, Input, TTL)

The /MI input prioritizes devices in vertically cascaded systems. It is connected to the /MF output of the previous device in the daisy chain. The /MI pin on the first device in the chain must be tied HIGH.

/MA (Device Match Flag, Output, TTL)

The /MA output is LOW when one or more valid matches occur during the current or the last previous compare cycle. The /MA output is not qualified by /EC or /MI, and reflects the match flag from that specific device's Status register. /MA will be reset when the active register set is changed.

/MM (Device Multiple Match Flag, Output, TTL)

The /MM output is LOW when more than one valid match occurs during the current or the last previous compare cycle. The /MM output is not qualified by /EC or /MI, and reflects the multiple match flag from that specific device's Status register. /MM will be reset when the active register set is changed.

/FF (Full Flag, Output, TTL)

If enabled in the Control register, the /FF output goes LOW when no empty memory locations exist within the device (and in the daisy chain above the device as indicated by the /FI pin). The System Full flag is the /FF pin of the last device in the daisy chain, and the Next Free address resides in the device with /FI LOW and /FF HIGH. If disabled in the Control register, the /FF output only depends on the /FI input (/FF = /FI).

/FI (Full Input, Input, TTL)

The /FI input generates a CAM-Memory-System-Full indication in vertically cascaded systems. It is connected to the /FF output of the previous device in the daisy chain. The /FI pin on the first device in a chain must be tied LOW.

/RESET (Reset, Input, TTL)

/RESET must be driven LOW to place the device in a known state before operation, which will reset the device to the conditions shown in Table 4 on page 9. LANCAM 'A' devices have a hardware reset that operates in parallel with the internal Power-on-reset circuitry, and sets the device to the same condition. For compatibility with the MU9C1480, the /RESET pin has an internal pull-up resistor and may be left unconnected. The /RESET pin should be driven by TTL levels, not directly by an RC timeout. /E must be kept HIGH during /RESET.

PIN DESCRIPTIONS Continued

TEST1, TEST2 (Test, Input, TTL)

These pins enable MUSIC production test modes that are not usable in an application. They should be connected to ground, either directly or through a pull-down resistor, or they may be left unconnected. These pins may not be implemented on all versions of these products.

VCC, GND (Positive Power Supply, Ground)

These pins are the power supply connections to the LANCAM. VCC must meet the voltage supply requirements in the Operating Conditions section relative to the GND pins, which are at 0 Volts (system reference potential), for correct operation of the device. All the ground and power pins must be connected to their respective planes with adequate bulk and high frequency bypassing capacitors in close proximity to the device.

FUNCTIONAL DESCRIPTION

The LANCAM is a content-addressable memory (CAM) with 16-bit I/O for network address filtering and translation, virtual memory, data compression, caching, and table lookup applications. The memory consists of static CAM, organized in 64-bit data fields. Each data field can be partitioned into a CAM and a RAM subfield on 16-bit boundaries. The contents of the memory can be randomly accessed or associatively accessed by the use of a compare. During automatic comparison cycles, data in the Comparand register is automatically compared with the "Valid" entries in the memory array. The Device ID can be read using a TCO PS instruction (see Table 12 on page 21).

The data inputs and outputs of the LANCAM are multiplexed for data and instructions over a 16-bit I/O bus. Internally, data is handled on a 64-bit basis, since the Comparand register, the mask registers, and each memory entry are 64 bits wide. Memory entries are globally configurable into CAM and RAM segments on 16-bit boundaries, as described in US Patent 5,383,146 assigned to MUSIC Semiconductors. Seven different CAM/RAM splits are possible, with the CAM width going from one to four segments, and the remaining RAM width going from three to zero segments. Finer resolution on compare width is possible by invoking a mask register during a compare, which does global masking on a bit basis. The CAM subfield contains the associative data, which enters into compares, while the RAM subfield contains the associated data, which is not compared. In LAN bridges, the RAM subfield could hold, for example, port-address and aging information related to the destination or source address information held in the CAM subfield of a given location. In a translation application, the CAM field could hold the dictionary entries, while the RAM field holds the translations, with almost instantaneous response.

Each entry has two validity bits (known as Skip bit and Empty bit) associated with it to define its particular type: empty, valid, skip, or RAM. When data is written to the active Comparand register, and the active Segment Control register reaches its terminal count, the contents of the Comparand register are automatically compared with the CAM portion of all the valid entries in the memory array. For added versatility, the Comparand register can be barrel-shifted right or left one bit at a time. A Compare instruction can then be used to force another compare between the Comparand register and the CAM portion of memory entries of any one of the four validity types. After a Read or Move from Memory operation, the validity bits of the location read or moved will be copied into the Status register, where they can be read from the Status register using Command Read cycles.

Data can be moved from one of the data registers (CR, MR1, or MR2) to a memory location that is based on the results of the last comparison (Highest-Priority Match or Next Free), or to an absolute address, or to the location pointed to by the active Address register. Data can also be written directly to the memory from the DQ bus using any of the above addressing modes. The Address register may be directly loaded and may be set to increment or decrement, allowing DMA-type reading or writing from memory.

Two sets of configuration registers (Control, Segment Control, Address, Mask Register 1, and Persistent Source and Destination) are provided to permit rapid context switching between foreground and background activities. Writes, reads, moves, and compares are controlled by the currently active set of configuration registers. The foreground set would typically be pre-loaded with values useful for comparing input data, often called filtering, while the background set would be pre-loaded with values useful for housekeeping activities such as purging old entries. Moving from the foreground task of filtering to the background task of purging can be done by issuing a single instruction to change the current set of configuration registers. The match condition of the device is reset whenever the active register set is changed.

FUNCTIONAL DESCRIPTION Continued

The active Control register determines the operating conditions within the device. Conditions set by this register's contents are reset, enable or disable Match flag, enable or disable Full flag, CAM/RAM partitioning, disable or select masking conditions, disable or select auto-incrementing or -decrementing the Address register, and select Standard or Enhanced modes. The active Segment Control register contains separate counters to control the writing of 16-bit data segments to the selected persistent destination, and to control the reading of 16-bit data segments from the selected persistent source.

There are two active mask registers at any one time, which can be selected to mask comparisons or data writes. Mask Register 1 has both a foreground and background mode to support rapid context switching. Mask Register 2 does not have this mode, but can be shifted left or right one bit at a time. For masking comparisons, data stored in the active selected mask register determines which bits of the comparand are compared against the valid contents of the memory. If a bit is set HIGH in the mask register, the same bit position in the Comparand register becomes a "don't care" for the purpose of the comparison with all the memory locations. During a Data Write cycle or a MOV instruction, data in the specified active mask register can also determine which bits in the destination will be updated. If a bit is HIGH in the mask register, the corresponding bit of the destination is unchanged.

The match line associated with each memory address is fed into a priority encoder where multiple responses are resolved, and the address of the highest-priority responder (the lowest numerical match address) is generated. In LAN applications, a multiple response might indicate an error. In other applications the existence of multiple responders may be valid.

Four input control signals and commands loaded into an instruction decoder control the LANCAM. Two of the four input control signals determine the cycle type. The control signals tell the device whether the data on the I/O bus represents data or a command, and is input or output. Commands are decoded by instruction logic and control moves, forced compares, validity bit manipulations, and the data path within the device. Registers (Control, Segment Control, Address, Next Free Address, etc.) are accessed using Temporary Command Override instructions. The data path from the DQ bus to/from data resources (comparand, masks, and memory) within the device are set until changed by Select Persistent Source and Destination instructions.

After a Compare cycle (caused by either a data write to the Comparand or mask registers, a write to the Control register, or a forced compare), the Status register contains the address of the Highest-Priority Matching location in that device, concatenated with its page address, along with flags indicating internal match, multiple match, and full. When the Status register is read with a Command Read cycle, the device with the Highest-Priority match will respond, outputting the System Match address to the DQ bus. The internal Match (/MA) and Multiple match (/MM) flags are also output on pins. Another set of flags (/MF and /FF) that are qualified by the match and full flags of previous devices in the system are also available directly on output pins, and are independently daisy-chained to provide System Match and Full flags in vertically cascaded LANCAM arrays. In such arrays, if no match occurs during a comparison, read access to the memory and all the registers except the Next Free register is denied to prevent device contention. In a daisy chain, all devices will respond to Command and Data Write cycles, depending on the conditions shown in Tables 5a and 5b on page 11, unless the operation involves the Highest-Priority Match address or the Next Free address; in which case, only the specific device having the Highest-Priority match or the Next Free address will respond.

A Page Address register in each device simplifies vertical expansion in systems using more than one LANCAM. This register is loaded with a specific device address during system initialization, which then serves as the higher-order address bits. A Device Select register allows the user to target a specific device within a vertically cascaded system by setting it equal to the Page Address Register value, or to address all the devices in a string at the same time by setting the Device Select value to FFFFH.

Figure 1a shows expansion using a daisy chain. Note that system flags are generated without the need for external logic. The Page Address register allows each device in the vertically cascaded chain to supply its own address in the event of a match, eliminating the need for an external priority encoder to calculate the complete Match address at the expense of the ripple-through time to resolve the highest-priority match. The Full flag daisy-chaining allows Associative writes using a Move to Next Free Address instruction which does not need a supplied address.

Figure 1b shows an external PLD implementation of a simple priority encoder that eliminates the daisy chain ripplethrough delays for systems requiring maximum performance from many CAMS.

OPERATIONAL CHARACTERISTICS

Throughout the following, "aaaH" represents a three-digit hexadecimal number "aaa," while "bbB" represents a twodigit binary number "bb." All memory locations are written to or read from in 16-bit segments. Segment 0 corresponds to the lowest order bits (bits 15–0) and Segment 3 corresponds to the highest order bits (bits 63–48).

THE CONTROL BUS

Refer to the Block Diagram on page 1 for the following discussion. The inputs Chip Enable (/E), Write Enable (/W), Command Enable (/CM), and Enable Daisy Chain (/EC) are the primary control mechanism for the LANCAM. The /EC input of the Control bus enables the /MF Match flag output when LOW and controls the daisy chain operation. Instructions are the secondary control mechanism. Logical combinations of the Control Bus inputs, coupled with the execution of Select Persistent Source (SPS), Select Persistent Destination (SPD), and Temporary Command Override (TCO) instructions allow the I/O operations to and from the DQ15–0 lines to the internal resources, as shown in Table 3 on page 8.

The Comparand register is the default source and destination for Data Read and Write cycles. This default state can be overridden independently by executing a Select Persistent Source or Select Persistent Destination instruction, selecting a different source or destination for data. Subsequent Data Read or Data Write cycles will access that source or destination until another SPS or SPD instruction is executed. The currently selected persistent source or destination can be read back through a TCO PS or PD instruction. The sources and destinations available for persistent access are those resources on the 64-bit bus: Comparand register, Mask Register 1, Mask Register 2, and the Memory array.

The default destination for Command Write cycles is the Instruction decoder, while the default source for Command Read cycles is the Status register.

Temporary Command Override (TCO) instructions provide access to the Control register, the Page Address register, the Segment Control register, the Address register, the Next Free Address register, and Device Select register. TCO instructions are only active for one Command Read or Write cycle after being loaded into the Instruction decoder.

The data and control interfaces to the LANCAM are synchronous. During a Write cycle, the Control and Data inputs are registered by the falling edge of /E. When writing to the persistently selected data destination, the Destination Segment counter is clocked by the rising edge of /E. During a Read cycle, the Control inputs are registered by the falling

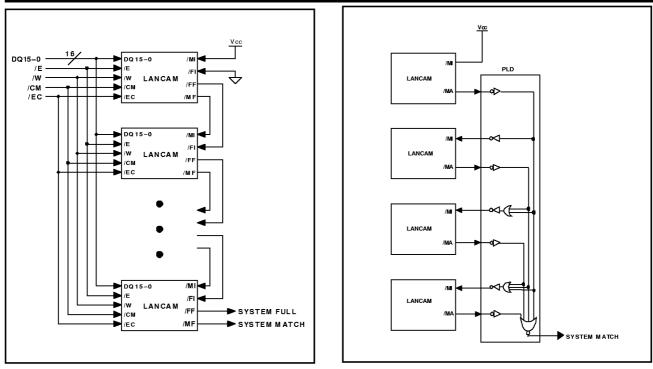


Figure 1a: Vertical Cascading



edge of /E, and the Data outputs are enabled while /E is LOW. When reading from the persistently selected data source, the Source Segment counter is clocked by the rising edge of /E.

THE REGISTER SET

The Control, Segment Control, Address, Mask Register 1, and the Persistent Source and Destination registers are duplicated, with one set termed the Foreground set, and the other the Background set. The active set is chosen by issuing Select Foreground Registers or Select Background Registers instructions. By default, the Foreground set is active after a reset. Having two alternate sets of registers that determine the device configuration allows for a rapid return to a foreground network filtering task from a background housekeeping task.

Writing a value to the Control register or writing data to the last segment of the Comparand or either mask register will cause an automatic comparison to occur between the contents of the Comparand register and the words in the CAM segments of the memory marked valid, masked by MR1 or MR2 if selected in the Control register.

Instruction Decoder

The Instruction decoder is the write-only decode logic for instructions and is the default destination for Command Write cycles. If an instruction's Address Field flag (bit 11) is set to a 1, it is a two-cycle instruction that is not executed immediately. For the next cycle only, the data from a Command Write cycle is loaded into the Address register and the instruction then completes at that address. The Address register will then increment, decrement, or stay at the same value depending on the setting of Control Register bits CT3 and CT2. If the Address Field flag is not set, the memory access occurs at the address currently contained in the Address register.

Control Register (CT)

The Control register is composed of a number of switches that configure the LANCAM, as shown in Table 8 on page 20. It is written or read using a TCO CT instruction. If bit 15 of the value written during a TCO CT is a 0, the device is reset (and all other bits are ignored). See Table 4 for the Reset states. Bit 15 always reads back as a 0. A write to the Control register causes an automatic compare to occur (except in the case of a reset). Either the Foreground or Background Control register will be active, depending on which register set has been selected, and only the active Control register will be written to or read from.

If the Match Flag is disabled through bits 14 and 13, the internal match condition, /MA(int), used to determine a daisy-chained device's response is forced HIGH as shown in Tables 5a and 5b on page 11, so that Case 6 is not possible, effectively removing the device from the daisy chain. With the Match Flag disabled, /MF=/MI and operations directed to Highest-priority Match locations are ignored. Normal operation of the device is with the /MF enabled. The Match Flag Enable field has no effect on the /MA or /MM output pins or Status Register bits. These bits always reflect the true state of the device.

If the Full Flag is disabled through bits 12 and 11, the device behaves as if it is full and ignores instructions to Next Free address. Additionally, writes to the Page Address register will be disabled. All other instructions operate normally. Additionally, with the /FF disabled, /FF=/FI. Normal operation of the device is with the /FF enabled. The Full Flag Enable field has no effect on the /FL Status Register bit. This bit always reflects the true state of the device.

The IEEE Translation control at bit 10 and bit 9 can be used to enable the translation hardware for writes to 64-bit resources in the device. When translation is enabled, the bits are reordered as shown in Figure 2.

Control Register bits 8–6 control the CAM/RAM partitioning. The CAM portion of each word may be sized from a full 64 bits down to 16 bits in 16-bit increments. The RAM portion can be at either end of the 64-bit word.

Compare masks may be selected by bits 5 and 4. Mask Register 1, Mask Register 2, or neither may be selected to mask compare operations. The address register behavior is controlled by bits 3 and 2, and may be set to increment, decrement, or neither after a memory access. Bits 1 and 0 set the operating mode: Standard as shown in Table 5a, or Enhanced as shown in Table 5b. The device will reset to the Standard mode, and follow the operating responses in

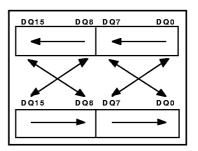


Figure 2: IEEE 802.3/802.5 Format Mapping

Cycle Type	Æ	/CM	/W	I/O Status	SPS	SPD	тсо	Operation	Notes
Cmd Write	L	L	L	IN				Load Instruction decoder	1
				IN			✓	Load Address register	2,3
				IN			✓	Load Control register	3
				IN			✓	Load Page Address register	3
				IN			✓	Load Segment Control register	3
				IN			✓	Load Device Select register	3
				IN				Deselected	10
Cmd Read	L	L	Н	OUT			\checkmark	Read Next Free Address register	3
				OUT			✓	Read Address register	3
				OUT				Read Status Register bits 15–0	4
				OUT				Read Status Register bits 31–16	5
				OUT			✓	Read Control register	3
				OUT			✓	Read Page Address register	3
				OUT			✓	Read Segment Control register	3
				OUT			✓	Read Device Select register	3
				OUT			✓	Read Current Persistent Source or Destination	3,11
				HIGH-Z				Deselected	10
Data Write	L	н	L	IN		\checkmark		Load Comparand register	6,9
				IN		~		Load Mask Register 1	7,9
				IN		\checkmark		Load Mask Register 2	7,9
				IN		\checkmark		Write Memory Array at address	7,9
				IN		\checkmark		Write Memory Array at Next Free address	7,9
				IN		~		Write Memory Array at Highest-Priority match	7,9
				IN				Deselected	10
Data Read	L	Н	Н	OUT	~			Read Comparand register	6, 9
				OUT	✓			Read Mask Register 1	8, 9
				OUT	✓			Read Mask Register 2	8, 9
				OUT	✓			Read Memory Array at address	8, 9
				OUT	✓			Read Memory Array at Highest-Priority match	7, 8
				HIGH-Z				Deselected	10
	Н	Х	Х	HIGH-Z				Deselected	

Notes:

1. Default Command Write cycle destination (does not require a TCO instruction).

- 2. Default Command Write Cycle destination (no TCO instruction required) if Address Field Flag was set in bit 11 of the instruction loaded in the previous cycle.
- Loaded or read on the Command Write of Read cycle immediately following a TCO instruction. Active for one Command Write or Read cycle only. NFA register cannot be loaded this way.
- 4. Default Command Read cycle source (does not require a TCO instruction).
- Default Command Read cycle source (does not require a TCO instruction) if the previous cycle was a Command Read of Status Register Bits 15-0. If next cycle is not a Command Read cycle, any subsequent Command Read cycle will access the Status Register Bits 15-0.
- 6. Default persistent source and destination on power-up and after Reset. If other resources were sources or destinations, SPD CR or SPS CR restores the Comparand register as the destination or source.
- 7. Selected by executing a Select Persistent Destination instruction.
- 8. Selected by executing a Select Persistent Source instruction.
- Access may require multiple 16-bit Read or Write cycles. The Segment Control register is used to control the selection of the desired 16-bit segment(s) by establishing the Segment counters' start and end limits and count values.
- 10. Device is deselected if Device Select register setting does not equal Page Address register setting, unless the Device Select Register is set to FFFFH which allows only write access to the device. (Writes to the Device Select register are always active.) Device may also be deselected under locked daisy-chain conditions as shown in Tables 5a and 5b.
- 11. A Command Read cycle after a TCO PS or TCO PD reads back the Instruction decoder bits that were last set to select a persistant source or destination. The TCO PS instruction will also read back the Device ID.

Table 3: Input/Output Operations

CAM Status	/RESET Condition
Validity bits at all memory locations	Skip = 0, Empty = 1 (empty)
Match and Full Flag outputs	Enabled
IEEE 802.3-802.5 Input Translation	Not Translated
CAM/RAM Partitioning	64 bits CAM, 0 bits RAM
Comparison Masking	Disabled
Address register auto-increment or -decrement	Disabled
Source and Destination Segment counters count ranges	00B to 011B; loaded with 00B
Address register and Next Free Address register	Contains all 0s
Page Address and Device Select registers	Contains all 0s (no change on software reset)
Control register after reset (including CT15)	Contains 0008H
Persistent Destination for Command writes	Instruction decoder
Persistent Source for Command reads	Status register
Persistent Source and Destination for Data reads and writes	Comparand register
Operating Mode	Standard
Configuration Register set	Foreground

Table 4: Device Control State after Reset

Table 5a. Standard Mode is identical to the operation of the original MU9C1480 LANCAM. When operating in Enhanced mode, it is not necessary to unlock the daisy chain with a NOP instruction before command or data writes after a non-matching compare, as required in the Standard mode.

Segment Control Register (SC)

The Segment Control register, as shown in Table 9 on page 21, is accessed using a TCO SC instruction. On read cycles, D15, D10, D5, and D2 will always read back as 0s. Either the Foreground or Background Segment Control register will be active, depending on which register set has been selected, and only the active Segment Control register will be written to or read from.

The Segment Control register contains dual independent incrementing counters with limits, one for data reads and one for data writes. These counters control which 16-bit segment of the 64-bit internal resource is accessed during a particular data cycle on the 16-bit data bus. The actual destination for data writes and source for data reads (called the persistent destination and source) are set independently with SPD and SPS instructions, respectively.

Each of the two counters consists of a start limit, an end limit, and the current count value which points to the segment to be accessed on the next data cycle. The current count value can be set to any segment, even if it is outside the range set by the start and end limits. The counters count up from the current count value to the end limit and then jump back to the start limit. If the current count is greater than the end limit, the current count value will increment to 3, then roll over to 0 and continue incrementing until the end limit is reached; it then jumps back to the start limit. If a sequence of data writes or reads is interrupted, the Segment Control register can be reset to its initial start limit values by using an RSC instruction. After the LANCAM is reset, both Source and Destination counters are set to count from Segment 0 to Segment 3 with an initial value of 0.

Page Address Register (PA)

The Page Address register is loaded using a TCO PA instruction followed by a Command Write cycle of a user selected 16-bit value (not FFFFH). The entry in the PA register is used to give a unique address to the different devices in a daisy chain. In a daisy chain, the PA value of each device is loaded using the SFF instruction to advance to the next device, as shown in the "Setting Page Address Register Values" section on page 15. A software reset (using the Control register) does not affect the Page Address register.

Device Select Register (DS)

The Device Select register is used to select a specific (target) device. The TCO DS instruction sets the 16-bit DS register to the value of the following Command Write cycle. The DS register can be read. A device is selected when its DS is equal to its PA value. In a daisy chain, setting DS = FFFFH will select all devices. However, in this case, the ability to read information out of the device is restricted as shown in Tables 5a and 5b. A software reset (using the Control register) does not affect the Device Select register.

Address Register (AR)

The Address register points to the CAM memory location to be operated upon when M@[AR] or M@aaaH is part of the instruction. It can be loaded directly by using a TCO AR instruction or indirectly by using an instruction requiring an absolute address, such as MOV aaaH,CR,V. After being loaded, the Address register value will then

be used for the next memory access referencing the Address register. A reset sets the Address register to zero.

Control Register bits CT3 and CT2 set the Address register to automatically increment or decrement (or not change) during sequences of Command or Data cycles. The Address register will change after executing an instruction that includes M@[AR] or M@aaaH, or after a data access to the end limit segment (as set in the Segment Control register) when the persistent source or destination is M@[AR] or M@aaaH.

Either the Foreground or Background Address register will be active, depending on which register set has been selected, and only the active Address register will be written to or read from.

Next Free Address Register (NF)

The LANCAM automatically stores the address of the first empty memory location in the Next Free Address register, which is then used as a memory address pointer for M@NF operations. The Next Free Address register, shown in Table 10 on page 21, can be read using a TCO NF instruction. By taking /EC LOW during the TCO NF instruction cycle, only the device with /FI LOW and /FF HIGH will output the contents of its Next Free Address register, which gives the Next Free address in a system of daisy-chained devices. The Next Free address may be read from a specific device in the chain by setting the Device Select register to the value of the desired device's Page address and leaving /EC HIGH.

The Full Flag daisy chain causes only the device whose /FI input is LOW and /FF output HIGH to respond to an instruction using the Next Free address. After a reset, the Next Free Address register is set to zero.

Status Register

The 32-bit Status register, shown in Table 11 on page 21, is the default source for Command Read cycles. Bit 31 is the internal Full flag, which will go LOW if the particular device has no empty memory locations. Bit 30 is the internal Multiple Match flag, which will go LOW if a Multiple match was detected. Bits 29 and 28 are the Skip and Empty Validity bits, which reflect the validity of the last memory location read. After a reset, the Skip and Empty bits will read 11 until a read or move from memory has occurred. The rest of the Status register down to bit 1 contains the Page address of the device and the address of the Highest-priority match as shown in Table 11 on page 21. After a reset or a no-match condition, the match address bits will be all 1s. Bit 0 is the internal Match flag, which will go LOW if a match was found in this particular device.

Comparand Register (CR)

The 64-bit Comparand register is the default destination for data writes and reads, using the Segment Control register to select which 16-bit segment of the Comparand register is to be loaded or read out. The persistent source and destination for data writes and reads can be changed to the mask registers or memory by SPS and SPD instructions. During an automatic or forced compare, the Comparand register is simultaneously compared against the CAM portion of all memory locations with the correct validity condition. Automatic compares always compare against valid memory locations, while forced compares, using CMP instructions, can compare against memory locations tagged with any specific validity condition.

The Comparand register may be shifted one bit at a time to the right or left by issuing a Shift Right or Shift Left instruction, with the right and left limits for the wrap-around determined by the CAM/RAM partitioning set in the Control register. During shift rights, bits shifted off the LSB of the CAM partition will reappear at the MSB of the CAM partition. Likewise, bits shifted off the MSB of the CAM partition will reappear at the LSB during shift lefts.

Mask Registers (MR1, MR2)

The Mask registers can be used in two different ways, either to mask compares or to mask data writes and moves. Either mask register can be selected in the Control register to mask every compare, or selected by instructions to participate in data writes or moves to and from Memory. If a bit in the selected mask register is set to a 0, the corresponding bit in the Comparand register will enter into a masked compare operation. If a Mask bit is a 1, the corresponding bit in the Comparand register will not enter into a masked compare operation. Bits set to 0 in the mask register cause corresponding bits in the destination register or memory location to be updated when masking data writes or moves, while a bit set to 1 will prevent that bit in the destination from being changed.

Either the Foreground or Background MR1 can be set active, but after a reset, the Foreground MR1 is active by default. MR2 incorporates a sliding mask, where the data can be replicated one bit at a time to the right or left with no wraparound by issuing a Shift Right or Shift Left instruction. The right and left limits are determined by the CAM/RAM partitioning set in the Control register. For a Shift Right the upper limit bit is replicated to the next lower bit, while for a Shift Left the lower limit bit is replicated to the next higher bit.

Case	Internal /EC(int)	Internal /MA (int)	External /MI	Device Select Reg.	Command Write ¹	Data Write	Command Read	Data Read
1	1	х	х	DS=FFFFH	YES ³	YES⁴	NO	NO
2	1	Х	Х	DS=PA	YES ³	YES⁴	YES	YES
3	1	Х	Х	DS≠FFFFH and	NO	NO	NO	NO
				DS≠PA				
4	0	Х	0	Х	NO	NO	NO⁵	NO
5	0	1	1	Х	NO	NO	NO⁵	NO
6 ²	0	0	1	Х	YES ³	YES⁴	YES⁵	YES

Table 5a: Standard Mode Device Select Response

Case	Internal /EC(int)	Internal /MA (int)	External /MI	Device Select Reg.	Command Write ¹	Data Write	Command Read	Data Read
1	1	х	х	DS = FFFFH	YES ³	YES⁴	NO	NO
2	1	Х	Х	DS = PA	YES ³	YES⁴	YES	YES
3	1	Х	Х	DS≠FFFFH and DS≠PA	NO	NO	NO	NO
4	0	0	0	Х	YES ^{3,6}	YES ^{4,7}	NO⁵	NO
5	0	1	Х	Х	YES ^{3,6}	YES ^{4,7}	NO⁵	NO
6 ²	0	0	1	Х	YES ³	YES⁴	YES⁵	YES

Table 5b: Enhanced Mode Device Select Response

NOTES:

1. Exceptions are:

- A) A write to the Device Select register is always active in all devices:
- B) A write to the Page Address register is active in the device with /FI LOW and /FF HIGH; and
- C) The Set Full Flag (SFF) instruction is active in the device with /FI LOW and /FF HIGH.
- If /MF is disabled in the Control register, /MA (Internal) is forced HIGH preventing a Case 6 response.
- 2. З. This is NO for a MOV instruction involving Memory at Next Free address if /FI is HIGH or the device is full.
- 4 This is NO if the Persistent Destination is Memory at Next Free address and /FI is HIGH or the device is full.
- 5 For a Command Read following a TCO NF instruction, this is YES if the device contains the first empty location in a daisy chain (i.e., /FI LOW and /FF HIGH) and NO if it does not.
- This is NO for a MOV or VBC instruction involving Memory at Highest-Priority match. 6.
- This is NO if the Persistent Destination is Memory at Highest-Priority match 7.

THE MEMORY ARRAY

Memory Organization

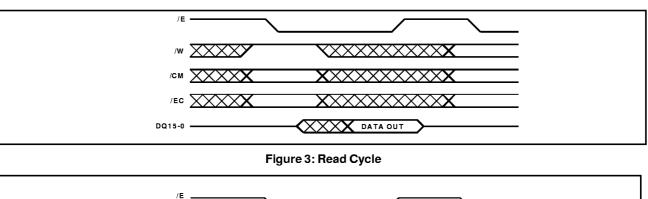
The Memory array is organized into 64-bit words with each word having an additional two validity bits (Skip and Empty). By default, all words are configured to be 64 CAM cells. However, bits 8-6 of the Control register can divide each word into a CAM field and a RAM field. The RAM field can be assigned to the least-significant or most-significant portion of each entry. The CAM/RAM partitioning is allowed on 16bit boundaries, permitting selection of the configuration shown in Table 8 on page 20, bits 8-6 (e.g., 001 sets the 48 MSBs to CAM and the 16 LSBs to RAM). Memory Array bits designated as RAM can be used to store and retrieve data associated with the CAM content at the same memory location.

Memory Access

There are two general ways to get data into and out of the memory array: directly or by moving the data through the Comparand or mask registers.

The first way, through direct reads or writes, is set up by issuing a Set Persistent Destination (SPD) or Set Persistent Source (SPS) command. The addresses for the direct access can be directly supplied; supplied from the Address register, supplied from the Next Free Address register, or supplied as the Highest-Priority Match address. Additionally, all the direct writes can be masked by either mask register.

The second way is to move data via the Comparand or mask registers. This is accomplished by issuing Data Move commands (MOV). Moves using the Comparand register can also be masked by either of the mask registers.





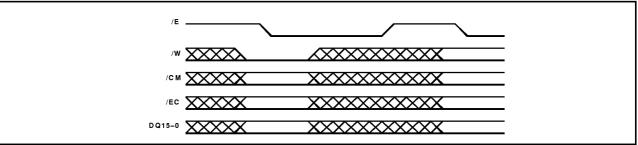


Figure 4: Write Cycle

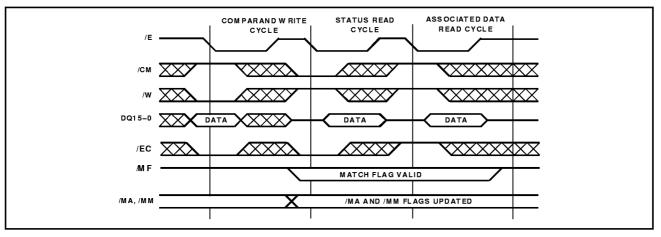


Figure 5: Cycle to Cycle Timing Example

I/O CYCLES

The LANCAM supports four basic I/O cycles: Data Read, Data Write, Command Read, and Command Write. The type of cycle is determined by the states of the /W and /CM control inputs. These signals are registered at the beginning of a cycle by the falling edge of /E. Table 2 on page 2 shows how the /W and /CM signals select the cycle type.

During Read cycles, the DQ15–0 outputs are enabled after /E goes LOW. During Write cycles, the data or command to be written is captured from DQ15–0 at the beginning of

the cycle by the falling edge of /E. Figures 3 and 4 show Read and Write cycles respectively. Figure 5 shows typical cycle-to-cycle timing with the Match flag valid at the end of the Comparand Write. Data writes and reads to the comparand, mask registers or memory occur in one to four 16-bit cycles, depending on the settings in the Segment Control register. The Compare operation automatically occurs during Data writes to the Comparand or mask registers when the destination segment counter reaches the end count set in the Segment Control register. If there was a match, the second cycle reads status or associated data, depending on the state of /CM. For cascaded devices,

/EC needs to be LOW at the start of the cycle prior to any cycle that requires a locked daisy chain, such as a Status register or associated data read after a match. If there is no match in Standard mode, the output buffers stay Hi-Z, and the daisy chain must be unlocked by taking /EC HIGH during a NOP or other non-functioning cycle, as indicated in Table 5a on page 11. Figure 6 shows how the internal /EC timing holds the daisy chain locking effect over into the next cycle. In the Enhanced mode, this NOP is not needed before data or command writes following a non-matching compare, as indicated by Table 5b on page 11. A single-chip system does not require daisy-chained match flag operation, hence /EC could be tied HIGH and the /MA pin or flag in the Status register used instead of /MF, allowing access to the device regardless of the match condition.

The minimum timings for the /E control signal are given in the Switching Characteristics section on page 24. Note that at minimum timings the /E signal is non-symmetrical, and that different cycle types have different timing requirements, as given in Table 7 on page 20.

COMPARE OPERATIONS

During a Compare operation, the data in the Comparand register is compared to all locations in the Memory array simultaneously. Any mask register used during compares must be selected beforehand in the Control register. There are two ways compares are initiated: Automatic and Forced compares.

Automatic compares perform a compare of the contents of the Comparand register against Memory locations that are tagged as "Valid," and occur whenever the following happens:

- The Destination Segment counter in the Segment Control register reaches its end limit during writes to the Comparand or mask registers.
- After a command write of a TCO CT is executed (except for a software reset), so that a compare is executed with the new settings of the Control register.

Forced compares are initiated by CMP instructions using one of the four validity conditions, V, R, S, and E. The forced compare against "Empty" locations automatically masks all 64 bits of data to find all locations with the validity bits set to "Empty," while the other forced compares are only masked as selected in the Control register.

VERTICAL CASCADING

LANCAMs can be vertically cascaded to increase system depth. Through the use of flag daisy-chaining, multiple devices will respond as an integrated system. The flag daisy chain allows all commands to be issued globally, with a response only in the device containing the Highest-Priority Matching or Next Free location. When connected in a daisy chain, the last device's Full flag and Match flag accurately report the condition for the whole string. A system in which LANCAMs are vertically cascaded using daisy-chaining of the flags is shown in Figure 1a on page 6.

To operate the daisy chain, the Device Select registers are set to FFFFH to enable all devices to execute Command Write and Data Write cycles. In normal operation, read cycles are enabled from the device with the highest-priority match by locking the daisy chain (see the "Locked Daisy Chain" section). An individual device in the chain may be targeted for a read or write operation by temporarily setting the Device Select registers to the Page address of the target device. Setting the Device Select registers back to FFFFH restores the operation of the entire daisy chain.

Match Flag Cascading

The Match Flag daisy chain cascading is used for three purposes: first, to allow operations on Highest-Priority Match addresses to be issued globally over the whole string; second, to provide a system wide match flag; third, to lock out all devices except the one with the Highest-Priority match for instructions such as Status reads after a match. The Match flag logic causes only the highestpriority device to operate on its Highest-Priority Match location while devices with lower-priority matches ignore Highest-Priority Match operations. The lock-out feature is enabled by the match flag cascading and the use of the /EC control signal, as shown in Tables 5a and 5b on page 11.

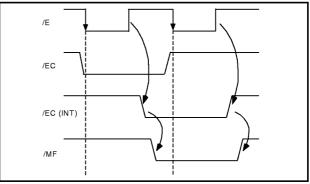


Figure 6: /EC(int) Timing Diagram

The ripple delay of the flags when connected in a daisy chain requires the extension of the /E HIGH time until the logic in all devices has settled out. In a string of "n" devices, the /E HIGH time should be greater than

tEHMFV + (n-2) · tMIVMFV

If the last device's Match flag is required by external logic or a state machine before the start of the next CAM cycle, one additional tMIVMFV should be added to the /E HIGH time along with the setup time and delays for the external logic.

Locked Daisy Chain

In a locked daisy chain, the highest-priority device is the one with /MI HIGH and /MF LOW. In the Standard mode, only this device will respond to command and data reads and writes, until the daisy chain has been unlocked by taking /EC HIGH. This allows reading the associated data field from only the Highest-Priority Match location anywhere in a string of devices, or the Match address from the Status register of the device with the match. It also permits updating the entry stored at the Highest-Priority Match location. In the Enhanced mode, devices are enabled to respond to some command and data writes, as noted in Table 5b on page 11, but not command and data reads.

Table 5a (Standard mode) and Table 5b (Enhanced mode) show when a device will respond to reads or writes and when it will not, based on the state of /EC(int), the internal match condition, and other control inputs. /EC is latched by the falling edge of /E. /EC(int) is registered from the latched /EC signal off the rising edge of /E, so it controls what happens in the next cycle, as shown in Figure 6. When /EC is first taken LOW in a string of LANCAM devices (and assuming the Device Select registers are set to FFFFH), all devices will respond to that command write or data write.

From then on the daisy chain will remain locked in each subsequent cycle as long as /EC is held LOW on the falling edge of /E in the current cycle. When the daisy chain is locked in the Standard mode, only the Highest-Priority Match device will respond (See Case 6 of Table 5a on page 11). If, for example, all of the CAM memory locations were empty, there would be no match, and /MF would stay HIGH. Since none of the devices could then be the Highest-Priority Match device, none will respond to reads or writes until the daisy chain is unlocked by taking /EC HIGH and asserting /E for a cycle.

If there is a match between the data in the Comparand register and one or more locations in memory, then only the

Highest-Priority Match device will respond to any cycle, such as an associated data or Status Register read. If there is not a match, then a NOP with /EC HIGH needs to be inserted before issuing any new instructions, such as Write to Next Free Address instruction to learn the data. Since Next Free operations are controlled by the /FI-/FF daisy chain, only the device with the first empty location will respond. If an instruction is used to unlock the daisy chain it will work only on the Highest-Priority Match device, if one exists. If none exists, the instruction will have no effect except to unlock the daisy chain. To read the Status registers of specific devices when there is no match requires the use of the TCO DS command to set DS=PA of each device. Single chip systems can tie /EC HIGH and read the Status register or the /MA and /MM pins to monitor match conditions, as the daisy chain lock-out feature is not needed in this configuration. This removes the need to insert a NOP in the case of a no-match.

When the Control register is set to the Enhanced mode, you can continue to write data to the Comparand register or issue a Move to Next Free Address instruction without first having to issue a NOP with /EC HIGH to unlock the daisy chain after a Compare cycle with no match, as indicated in cases 4 and 5 of Table 5b on page 11. In this mode, data write cycles as well as command write cycles are enabled in all devices even when /EC is LOW. Exceptions are data writes, moves, or VBC instructions involving HM, which occur only in the device with the highest match; and data writes or move instructions involving NF, which occur only in the device with /FI LOW and /FF HIGH. The Enhanced mode speeds up system performance by eliminating the need to unlock the daisy chain before Command or Data Write cycles.

Full Flag Cascading

The Full Flag daisy chain cascading is used for three purposes: first, to allow instructions that address Next Free locations to operate globally; second, to provide a system wide Full flag; third, to allow the loading of the Page Address registers during initialization using the SFF instruction. The full flag logic causes only the device containing the first empty location to respond to Next Free instructions such as MOV NF,CR,V, which will move the contents of the Comparand register to the first empty location in a string of devices and set that location Valid, so it will be available for the next automatic compare. With devices connected as in Figure 1a on page 6, the /FF output of the last device in a string provides a full indication for the entire string.

IEEE 802.3/802.5 Format Mapping

To support the symmetrical mapping between the address formats of IEEE 802.3 and IEEE 802.5, the LANCAM provides a bit translation facility. Formally expressed, the nth input bit, D(n), maps to the xth output bit, Q(x), through the following expressions:

$$D(n) = Q(7-n) \text{ for } 0 \le n \le 7,$$

 $D(n) = Q(23-n) \text{ for } 8 \le n \le 15$

Setting Control Register Bits 10 and 9 selects whether to persistently translate, or persistently not to translate, the data written onto the 64-bit internal bus. The default condition after a Reset command is not to translate the incoming data. Figure 2 on page 7 shows the bit mapping between the two formats.

INITIALIZING THE LANCAM

Initialization of the LANCAM is required to configure the various registers on the device. Since a Control register reset establishes the operating conditions shown in Table 4 on page 9, restoration of operating conditions better suited for the application may be required after a reset, whether using the Control Register reset, or the /RESET pin. When the device powers up, the memory and registers are in an unknown state, so the /RESET pin must be asserted to place the device in a known state.

Setting Page Address Register Values

In a vertically cascaded system, the user must set the individual Page Address registers to unique values by using the Page Address initialization mechanism. Each Page Address register must contain a unique value to prevent bus contention. This process allows individual device selection. The Page Address register initialization works as follows: Writes to Page Address registers are only active for devices with /FI LOW and /FF HIGH. At initialization, all devices are empty, thus the top device in the string will respond to a TCO PA instruction, and load its PA register. To advance to the next device in the string, a Set Full Flag (SFF) instruction is used, which is also only active for the device with /FI LOW and /FF HIGH. The SFF instruction changes the first device's /FF to LOW, although the device really is empty, which allows the next device in the string to respond to the TCO PA instruction and load its PA register. The initialization proceeds through the chain in a similar manner filling all the PA registers in turn. Each device must have a unique Page Address value stored in its PA register, or contention will result. After all the PA registers are filled, the entire string is reset through the Control register, which does not change the values stored in the individual PA registers. After the reset, the Device Select registers are usually set to FFFFH to enable operation in Case 1 of Table 5a on page 11. The Control registers and the Segment Control registers are then set to their normal operating values for the application.

Vertically Cascaded System Initialization

Table 6 shows an example of code that initializes a daisychained string of LANCAM devices. The initialization example shows how to set the Page Address registers of each of the devices in the chain through the use of the Set Full Flag instruction, and how the Control registers and Segment counters of all the LANCAM devices are set for a typical application. Each Page Address register must contain a unique value (not FFFFH) to prevent bus contention.

For typical daisy chain operation, data are loaded into the Comparand registers of all the devices in a string simultaneously by setting DS=FFFFH. Since reading is prohibited when DS=FFFFH except for the device with a match, for a diagnostic operation you need to select a specific device by setting DS=PA for the desired device to be able to read from it. Refer to Tables 5a and 5b on page 11 for preconditions for reading and writing.

Initialization for a single LANCAM is similar. The Device Select register in this case is usually set to equal the Page Address register for normal operations. Also, the dedicated /MA flag output can be used instead of /MF, allowing /EC to be tied HIGH.

OPERATIONAL CHARACTERISTICS Continued

Cycle Type	Op-Code	Control Bus			JS	Comments	
	on DQ Bus	/E	/CM	/W	/EC		
Command Read		L	L	Н	Н	Clear power-up anomalies	
Command Write	TCO DS	L	L	L	н	Target Device Select Register to disable local device section	
Command Write	FFFFH	L	L	L	н	Disable Device Select feature	
Command Write	тсо ст	L	L	L	н	Target Control register for reset	
Command Write	0000H	L	L	L	н	Causes Reset	1
Command Write	TCO PA	L	L	L	н	Target Page Address register to set page for cascaded operation	2
Command Write	nnnnH	L	L	L	н	Page Address value	2
Command Write	SFF	L	L	L	н	Set Full flag; allows access to next device (repeat previous	2,3
						2 cycles plus this one for each device in chain	
Command Write	тсо ст	L	L	L	н	Target Control register for reset of Full flags, but not Page address	1
Command Write	0000H	L	L	L	н	Causes Reset	1
Command Write	тсост	L	L	L	н	Target Control register for initial values	4
Command Write	8040H	L	L	L	н	Control register value	4
Command Write	TCO SC	L	L	L	н	Target Segment Counter Control register	
Command Write	3808H	L	L	L	н	Set both Segment Counters to write to Segment 1, 2, and 3 and	4
						read from Segment 0	
Command Write	SPSM@HM	L	L	L	н	Set Data Reads from Segment 0 of the Highest-priority match	

1. Toggling the /Reset pin generates the same effect as this reset of the Control register, but good programming practice dictates a software reset for initialization to account for all possible prior conditions.

2. This instruction may be omitted for a single LANCAM application.

3. The last SFF will cause the /FF pin in the last chip in a daisy chain to go LOW. In a daisy chain, DS needs to be set equal to PA to read out a particular chip prior to a match condition.

A typical LANCAM control environment: Enable match flag; Enable full flag; 48 CAM bits, 16 RAM bits; Disable comparison masking; and Enable address increment. See Table 8 for Control Register bit assignments.

Table 6: Example Initialization Routine

INSTRUCTION SET DESCRIPTIONS*

Instruction: Select Persistent Source (SPS) Binary Op-Code: 0000 f000 0000 0sss

f Address Field flagt

Selected source 222

This instruction selects a persistent source for data reads. until another SPS instruction changes it or a reset occurs. The default source after reset for Data Read cycles is the Comparand register. Setting the persistent source to M@aaaH loads the Address register with "aaaH" and the first access to that persistent source will be at aaaH, after which the AR value increments or decrements as set in the Control register. The SPS M@[AR] instruction does the same except the current Address Register value is used.

Instruction: Select Persistent Destination (SPD) Binary Op-Code: 0000 f001 mmdd dvvv

f	Address Field flag†
mm	Mask Register select
ddd	Selected destination

vvv Validity setting for Memory Location destinations

This instruction selects a persistent destination for data writes, which remains until another SPD instruction changes it or a reset occurs. The default destination for Data Write cycles is the Comparand register after a reset. When the destination is the Comparand register or the memory array, the data written may be masked by either Mask Register 1 or Mask Register 2, so that only destination bits corresponding to bits in the mask register set to 0 will be modified. An automatic compare will occur after writing the last segment of the Comparand or mask registers, but not after writing to memory. Setting the persistent destination to M@aaaH loads the Address register with "aaaH," and the first access to that persistent destination will be at aaaH, after which the AR value increments or decrements as set in the Control register. The SPD M@[AR] instruction does the same except the current Address Register value is used.

INSTRUCTION SET DESCRIPTIONS* Continued

Instruction: Temporary Command Override (TCO) Binary Op-Code: 0000 0010 00dd d000 ddd Register selected as source or destination for only the next Command Read or Write cycle

The TCO instruction selects a register as the source or destination for only the next Command Read or Write cycle, so a value can be loaded or read out of the register. Subsequent Command Read or Write Cycles revert to reading the Status register and writing to the Instruction decoder. All registers but the NF, PS, and PD can be written to, and all can be read from. The Status register is only available via non-TCO Command Read cycles. Reading the PS register also outputs the Device ID on bits 15–4 as shown in Table 12 on page 21.

Instruction: Data Move (MOV) Binary Op-Code: 0000 f011 mmdd dsss or 0000 f011 mmdd dvss f Address Field flag†

mm	Mask Register select
ddd	Destination of data
SSS	Source of data
v	Validity setting if destination is a
-	Memory location

The MOV instruction performs a 64-bit move of the data in the selected source to the selected destination. If the source or destination is aaaH, the Address register is set to "aaaH." For MOV instructions to or from aaaH or [AR], the Address register will increment or decrement from that value after the move completes, as set in the Control register. Data transfers between the Memory array and the Comparand register may be masked by either Mask Register 1 or Mask Register 2, in which case, only those bits in the destination which correspond to bits in the selected mask register set to 0 will be changed. A Memory location used as a destination for a MOV instruction may be set to Valid or left unchanged. If the source and destination are the same register, no net change occurs (a NOP).

Instruction: Validity Bit Control (VBC) Binary Op-Code: 0000 f100 00dd dvvv

f Address Field flag†

ddd Destination of data

vvv Validity setting for Memory location

The VBC instruction sets the Validity bits at the selected memory locations to the selected state. This feature can be used to find all valid entries by using a repetitive sequence of CMP V through a ms of all 1s followed by a VBC HM, S. If the VBC target is aaaH, the Address register is set to "aaaH." For VBC instructions to or from aaaH or [AR], the Address register will increment or decrement from that value after the operation completes, as set in the Control register.

Instruction: Compare (CMP) Binary Op-Code: 0000 0101 0000 0vvv vvv Validity condition

A CMP V, S, or R instruction forces a Comparison of Valid,

Skipped, or Random entries against the Comparand register through a mask register, if one is selected. During a CMP E instruction, the compare is only done on the Validity bits and all data bits are automatically masked.

Instruction: Special Instructions Binary Op-Code: 0000 0110 00dd drrr ddd Target resource rrr Operation

These instructions are a special set for the LANCAM to accommodate the added features over the MU9C1480. Two alternate sets of configuration registers can be selected by using the Select Foreground and Select Background Registers instructions. These registers are the Control, Segment Control, Address, Mask Register 1, and the PS and PD registers. An RSC instruction resets the Segment Control register count values for both the Destination and Source counters to the original Start limits. The Shift instructions shift the designated register one bit right or left. The right and left limits for shifting are determined by the CAM/RAM partitioning set in the Control register. The Comparand register is a barrel-shifter, and for the example of a device set to 64 bits of CAM executing a Shift Comparand Right instruction, bit 0 is moved to bit 63, bit 1 is moved to bit 0, and bit 63 is moved to bit 62. For a Shift Comparand Left instruction, bit 63 is moved to bit 0, bit 0 is moved to bit 1, and bit 62 is moved to bit 63. MR2 acts as a sliding mask, where for a Shift Right instruction bit 1 is moved to bit 0, while bit 0 "falls off the end," and bit 63 is replicated to bit 62. For a Shift Mask Left instruction, bit 0 is replicated to bit 1, bit 62 is moved to bit 63, and bit 63 "falls off the end." With shorter width CAM fields, the bit limits on the right or left move to match the width of CAM field.

Instruction: Set Full Flag (SFF) Binary Op-Code: 0000 0111 0000 0000*

The SFF instruction is a special instruction used to force the Full flag LOW to permit setting the Page Address register in vertically cascaded systems.

Instruction: No Operation (NOP) Binary Op-Code: 0000 0011 0000 0000

The NOP (No-OP) belongs to the MOV instructions, where a register is moved to itself. No change occurs within the device. This instruction is useful in unlocking the daisy chain in Standard mode.

Notes:

* Instruction cycle lengths given in Table 7 on page 20.

 \dagger If f=1, the instruction requires an absolute address to be supplied on the following cycle as a Command write. The value supplied on the second cycle of the instruction will update the Address register. After operations involving M@[AR] or M@aaaH, the Address register will increment or decrement depending on the setting in the Control register.

INSTRUCTION SET SUMMARY

INS dst,src[msk],val Operation Mnemonic Ope-Code NS: Instruction memonic Masked by MR1 SPD M@HMMRTIE 012DH Masked by MR2 SPD M@HMMRTIE 012DH mask: Mask register SPD M@HMMRTIE 012DH Masked by MR2 SPD M@HMMRTIE 012DH Comparad Register SPS KR 002DH Masked by MR2 SPD M@HMMRTIE 012PH Masked by MR2 SPD M@HMMRTIE 012PH Masked by MR2 SPD M@HMMRTIE 014PH Masked by MR2 SPD M@NFMMRTIE 014PH Masked by MR2 SPD M@NFMRTIE 014PH Masked by MR2 SPD M@NFMRTIE		IC FORMAT		Instruction: Select Pers	istent Destinatio	n <i>Cont.</i>
NS: Instruction memonic dat: Destination of the data ser: Source Source Mem.atHighest-Pio.Match, Emp. SPD.M@HMMR1; Masked by MR1 Other SPD.M@HMMR1; SPD.M@HMMR1; Masked by MR1 SPD.M@HMMR1; SPD.M@HMMR1; Masked by MR1 Other SPD.M@HMMR1; SPD.M@HMMR1; Masked by MR1 SPD.M@HMMR1; SPD.M@HMMR1; SPD.M@HMMR1; SPD.M@HMMR1; SPD.M@NF1; Masked by MR1 Other SPD.M@NF1; Masked by MR1 Nomenoic Operation Operation Masked by MR1 SPD.M@NF1; SPD.M@NF1; Masked by MR1 SPD.M@NF1; SPD.M@NF1; Masked by MR1 SPD.M@NF1; SPD.M@NF1; Masked by MR1 SPD.M@NF1; SPD.M@NF1; SPD.M@NF1; Masked by MR1 SPD.M@NF1; Masked by MR1 SPD.M@NF1; SPD.M@NF1; Masked by MR1 SPD.M@NF1; SPD.M@NF1; Masked by MR1 SPD.M@NF1; Masked by MR1 </th <th>INS dst,si</th> <th>rc[msk],val</th> <th></th> <th>Operation</th> <th>Mnemonic</th> <th>Op-Code</th>	INS dst,si	rc[msk],val		Operation	Mnemonic	Op-Code
INS: Instruction mnemolic dat: Destination of the data mack: Dask routing of the data mack: Mask register used val: Validity condition set at the location written Masked by MR2 SPD M@HMMR1jE 0180H Instruction: Select Persistent Source Operation Mnemonic Op-Code SPS NR1 Mem. at High-selfor. Match, Skip SPD M@HMMR1jS 012H Masked by MR2 SPD M@HMMR1jS 012H Memory Array at Address SPS M@JAM 000H Memory Array at Address SPD CR[MR1] 010H Masked by MR2 SPD M@JAMMR1jS 013H Masked by MR1 SPD M@JAMMR1jS 013H Masked by MR1 SPD M@JAMMR1jS 013H Masked by MR1 SPD M@JAMMR1jS <td></td> <td></td> <td></td> <td></td> <td></td> <td></td>						
det: Destination of the data msk: Mask register used Masked by MR2 SPD M@HM_MR1[S 012EH Masked by MR2 val: Validity condition set at the location written Masked by MR2 SPD M@HM_MR1[S 012EH Masked by MR2 013EH Masked by MR1 013	INS: Instruction mnemonic					
src: Source of the data msk: Mask register used val: Validly condition set at the location written Instruction: Select Persistent Source Operation Make de by MR1 SPD M@HM[MR2]S OteF Masked by MR1 SPD M@HM[MR2]S OteF Masked by MR1 SPD M@HM[MR2]S OteF Masked by MR1 SPD M@HM[MR2]R OteF Masked by MR1 Masked by MR1						
mask: Mask register used val: Validity condition set at the location written val: Validity condition set at the location written Mem. at Highest-Prio. Match, Skip SPD M@HMS (MR1); 0 016EH Masked by MR1 SPD M@HM (MR2); 0 116EH Masked by MR1 SPD M@HM (MR1); 0 016FH Masked by MR2 SPD M@HM; 0 017FH Masked by MR2 SPD M@HM; 0 017FH Masked by MR2 SPD M@HM; 0 016FH Masked by MR2 SPD M@HM; 0 016FH Masked by MR2 SPD M@HM; 0 016FH Masked by MR2 SPD M@HM; 0 017FH Masked by MR1 MOV CR, MM; 0 005H Masked by MR1 M		.			er e mêr mîrîn ejte	e in ibi i
Intak, Maske dey MR1 SPD M@HM[MR1]S 016EH Maske de by MR1 SPD M@HM[MR1]R 016FH Maske de by MR1 SPD M@HM[MR1]R 016FH Maske de by MR1 SPD M@HM[MR1]R 016FH Memory Array at Address SPS M@BaaH 0000H Mem. at Highest-Prio. Match SPS M@BaaH 0000H Mem. at Highest-Prio. Match SPD CR[MR2] 0100H Masked by MR1 SPD CR[MR2] 0100H Masked by MR1 SPD M@NF[MR1]E 0137H Masked by MR2 SPD CR[MR2] 0100H Masked by MR1 SPD M@NF[MR1]E 0137H Masked by MR2 SPD M@AR[[MR1]L] 0160H Masked by MR1 SPD M@NF[MR1]E 017H Masked by MR2 SPD M@AR[MR1]E 0160H Masked by MR1 SPD M@NF[MR1]E 017H Masked by MR2 SPD M@AR[MR1]E 0160H Masked by MR1 SPD M@NF[MR1]E 017H				Mem at Highest-Prio Match Skin	SPDM@HMS	012EH
Vall: Vallicity condition set at the location Written Masked by MR2 SPD M@HM[MR2],S 01AEH Instruction: Select Persistent Source Operation Mem at High-Pric, Match, Radou SPD M@HM[MR1],R 016FH Mask Register 1 SPS M SPS M 0000H Mask Register 2 SPS M 0000H Memory Aray at Address SPS M@AR 0000H Memory Aray at Address SPS M@AR 0000H Mask Register 1 SPS M@HM 0005H Masked by MR1 SPD CR[MR1] 0160H Masked by MR1 SPD CR[MR1] 0160H Masked by MR1 SPD CR[MR2] 0180H Masked by MR1 SPD CR[MR2] 0180H Masked by MR1 SPD M@ARF,R 017H						
Instruction: Select Persistent Source Mem.at. High-show Math., Random SPD M@HM,R 012FH Comparand Register SPS MB1 000H Masked by MR1 SPD M@HM[MR1]R 014FH Mask Register 1 SPS MB1 000H Masked by MR2 SPD M@HM[MR1]R 014FH Memory Array at Address SPS M@DaaaH 000H Masked by MR1 SPD M@NF[MR1]L 013H Mem. at High-st-Prio. Match SPS M@DaaaH 000H Masked by MR1 SPD M@NF[MR1]E 013H Mem. at Next Free Addr., Skip SPD M@NF[MR1]E 013H Masked by MR1 SPD M@NF[MR1]E 013H Masked by MR1 SPD CR[MR1] 014H Masked by MR1 SPD M@NF[MR1]E 013H Masked by MR1 SPD CR[MR1] 014H Masked by MR1 SPD M@NF[MR1]S 013H Masked by MR1 SPD CR[MR1]2 014H Masked by MR1 SPD M@NF[MR1]S 013H Masked by MR1 SPD M@NF[MR1]2 014H Masked by MR1 SPD M@NF[MR1]S 013H Masked by MR1 SPD M@NF[MR1]2 014H Masked by MR1 SPD M@NF[MR	val: Validity condition set a	t the location written				
Masked by MR1 SPD M@htM[MR1]R OIAFH Mask Register SPS MR1 000H Mask Register 1 SPS MR1 000H Mask Register 2 SPS MR1 000H Memory Aray at Addr.ess SPS M@aaaH 000H Instruction: Select Persistent Destination Mem at Next Free Addr., Skip SPD M@NF[MR1]E 013H Masked by MR1 SPD CR[MR1] 010H Masked by MR1 SPD M@NF[MR1]S 013H Masked by MR1 SPD CR[MR1] 010H Masked by MR1 SPD M@NF[MR1]S 013H Masked by MR1 SPD CR[MR1] 010H Masked by MR1 SPD M@NF[MR1]S 013H Masked by MR1 SPD M@NF[MR1]S 010H Masked by MR1 SPD M@NF[MR1]S 013H Masked by MR1 SPD M@NF[MR1]S 010H Masked by MR2 SPD M@NF[MR1]S 013H Masked by MR1 SPD M@AAR[MR1] 010H						
Operation Mmemonic Op-Code (mask Register 1 Mask Register 3 SPS CR 0000H Mask Register 1 SPS MR1 0001H Mem. at Next Free Addr., Valid SPD M@NFV 0134H Mask Register 2 SPS MR2 0002H SPD M@NFW1V 0134H Memory Array at Address SPS M@aam 0804H Mem. at Next Free Addr., Empty SPD M@NFW1V 0134H Memory Array at Address SPS M@aam 0804H Mem. at Next Free Addr., Empty SPD M@NFE 0138H Masked by MR1 SPD CR 0005H Mem. at Next Free Addr., Empty SPD M@NFE 0138H Masked by MR2 SPD CR 0100H Masked by MR1 SPD M@NFMR2,E 0186H Masked by MR2 SPD CR[MR2] 0100H Masked by MR1 SPD M@NFRE, 0137H Masked by MR2 SPD M@NFR2,V 0140H Masked by MR2 SPD M@NFRE, 0137H Masked by MR1 SPD M@ARJ[MR1],V 0144H Masked by MR2 SPD M@NFRE, 0137H Masked by MR2 SPD M@ARJ[MR1],V 0144H Masked by MR1 SPD M@ARJ[MR1],N	Instruction: Select Pers	istent Source		, j		
Comparand Register SPS CR Cooperation Matched by MR1 SPD M@NF;V O134H Mask Register 2 SPS MR1 0001H Mem. at Next Free Addr., Valid SPD M@NF;V 0134H Memory Array at Address SPS M@AM 0002H Mem. at Next Free Addr., Valid SPD M@NF;W 0134H Memory Array at Address SPS M@AM 0002H Mem. at Next Free Addr., Valid SPD M@NF;W 0134H Memory Array at Address SPS M@AM 0002H Masked by MR1 SPD M@NF;MR1;E 0134H Instruction: Select Persistent Destination Memman CopeCode SPD M@NF;MR1;E 0175H Masked by MR1 SPD CR[MR2] 0160H Mesked by MR2 SPD M@NF;MR1;E 0178H Masked by MR1 SPD M@NF;MR1;E 0160H Mesked by MR2 SPD M@NF;MR1;E 0178H Masked by MR1 SPD M@NF;MR1;E 0164H Masked by MR2 SPD M@NF;MR1;E 0178H Masked by MR1 SPD M@AR;[MR1];V 0164H Masked by MR2 SPD M@NF;MR1;E 0178H Masked by MR1 SPD M@AR;[MR1];MR1];V 0164H <td< td=""><td>Operation</td><td>Mnemonic C</td><td>Dp-Code</td><td>· · ·</td><td></td><td></td></td<>	Operation	Mnemonic C	Dp-Code	· · ·		
Mask Register 1 SPS MR1 0001H Mem. at Next Free Addr., Valid SPD M@NF_W 0134H Mask Register 2 SPS M@(AR) 0004H Masked by MR1 SPD M@NF[MR1],V 0174H Memory Array at Address SPS M@(AR) 0004H Masked by MR1 SPD M@NF[MR1],V 0184H Mem. at Nighest-Prio. Match SPS M@(AR) 0004H Masked by MR1 SPD M@NF[MR1],V 0184H Mem. at Next Free Addr., Skip SPD M@NF[MR1],E 0135H Masked by MR1 SPD M@NF[MR2],E 0136H Masked by MR1 SPD CR[MR2] 0100H Masked by MR1 SPD M@NF[MR2],S 0136H Masked by MR1 SPD M@(AR] 0100H Masked by MR1 SPD M@(NF[MR1],S 017H Masked by MR1 SPD M@(AR] 0100H Masked by MR1 SPD M@(NF[MR1],S 018H Masked by MR1 SPD M@(AR] SPD M@(AR] 017H Masked by MR2 SPD M@(NF[MR1],S 018H Masked by MR1 SPD M@(AR] SPD M@(AR] OPD M@(AR] OPD M@(AR] OPD M@(AR] 017H Masked by MR2 SP			-	Masked by MR2	SPD M@HM[MR2],R	UIAFH
Mask Register 2 SPS MR2 0002H Masked by MR1 SPD M@NF[MR1],V 0174H Memory Array at Address SPS M@aaaH 0804H Masked by MR2 SPD M@NF[MR2],V 0184H Mem. at Highest-Prio. Match SPS M@hm 0005H Masked by MR1 SPD M@NF[MR2],V 0184H Mem. at Highest-Prio. Match SPD CR[MR1] 0005H Masked by MR1 SPD M@NF[MR1],E 0135H Instruction: Select Persistent Destination Operation Memony Array at Address SPD CR[MR1] 0100H Masked by MR1 SPD M@NF[S S] 0136H Masked by MR1 SPD CR[MR1] 0100H Masked by MR2 SPD M@NF[MR1],R 0176H Masked by MR1 SPD M@NF[MR1],R 0170H Masked by MR2 SPD M@NF[MR1],R 0176H Masked by MR1 SPD M@NF[MR1],R 0170H Masked by MR2 SPD M@NF[MR1],R 0177H Masked by MR1 SPD M@NF[MR1],R 0177H Masked by MR2 SPD M@NF[MR1],R 0177H Masked by MR1 SPD M@AR1],W 014H Masked by MR2 SPD M@NF[MR1],R 0177H Masked by M						010411
Memory Array at Addr. Reg. SPS M@(AR) 0004H Masked by MR2 SPD M@(NF[MR2],V) 0194H Memory Array at Address SPS M@AH 0005H Masked by MR2 SPD M@(NF[MR2],V) 0194H Instruction: Select Persistent Destination Memonic Op-Code Masked by MR1 SPD M@(NF[MR2],S) 0135H Comparand Register SPD CR[MR1] 0100H Masked by MR1 SPD M@(NF[MR2],S) 016H Masked by MR1 SPD CR[MR2] 0130H Masked by MR1 SPD M@(NF[MR2],S) 016H Masked by MR2 SPD M@(NF[MR1],S) 016H Masked by MR1 SPD M@(NF[MR2],R) 017H Masked by MR1 SPD MM1 0100H Masked by MR2 SPD M@(NF[MR2],R) 017H Masked by MR1 SPD M@(AR][MR2],V 012H Masked by MR2 SPD M@(NF[MR2],R) 017H Masked by MR1 SPD M@(AR][MR2],V 012H Masked by MR2 SPD M@(NF[MR2],R) 017H Masked by MR1 SPD M@(AR][MR1],V 016H Masked by MR2 SPD M@(AR][MR1],R 017H Masked by MR1 SPD M@(AR][MR1],R 012H						
Memory Array at Address SPS M@aaal 0804H Mem. at Highest-Prio. Match SPS M@HM 0005H Instruction: Select Persistent Destination Mem. at Next Free Addr., Empty SPD M@NFE 0135H Operation Mnemonic Op-Code Masked by MR1 SPD CR[MR1] 0140H Masked by MR1 SPD CR[MR1] 0140H Masked by MR1 SPD M@NFES 0136H Masked by MR1 SPD CR[MR2] 0180H Masked by MR1 SPD M@NFR 0137H Mask Register 1 SPD M@(AR][MR1],V 016H Masked by MR2 SPD M@(NFR1],R 017H Masked by MR1 SPD M@(AR][MR1],V 016H Masked by MR2 SPD M@(NF[R1],R 017H Masked by MR1 SPD M@(AR][MR1],V 016H Masked by MR2 SPD M@(NF[R1],R 017H Masked by MR1 SPD M@(AR][MR1],S 016H Masked by MR2 SPD M@(AR][MR1],A 012H Mem. at Addr. Reg. set Empty Masked by MR1 SPD M@(AR][MR1],S 016H Masked by MR1 SPD M@(AR][MR1],S 016H Masked by MR1 SPD M@(AR][MR1],S 016H						
Mem. at Highest-Prio. Match SPS M@HM 0005H Mem, at Next Free Addr., Empty Masked by MR1 SPD M@NF[M1],E 0135H Instruction: Select Persistent Destination Operation Mnemonic Op-Code Masked by MR2 SPD M@NF[M1],E 0135H Comparand Register SPD CR[MR1] 0100H Masked by MR1 SPD M@NF[M1],S 0176H Masked by MR1 SPD CR[MR2] 0180H Mem. at Next Free Addr., Skip SPD M@NF[M1],S 0176H Mask Register 1 SPD M@(AR] 0108H Masked by MR1 SPD M@(NF[M1],R 0177H Masked by MR1 SPD M@(AR] 0108H Masked by MR1 SPD M@(AR] 0177H Masked by MR1 SPD M@(AR][MR1],V 0124H Masked by MR1 SPD M@(AR][MR1],E 017FH Masked by MR1 SPD M@(AR][MR1],E 0125H Masked by MR1 SPD M@(AR][MR1],E 0125H Masked by MR1 SPD M@(AR][MR1],E 0125H Masked by MR1 SPD M@(AR][MR1],E 0126H Masked by MR1 SPD M@(AR][MR1],E 0125H Masked by MR1 SPD M@(AR][MR1],E 0126H Masked by				Masked by MRZ	SFD W@NF[Wh2],V	01040
Masked by MR1 SPD M@NF[MR1]E 0175H SPD M@NF[MR1]E 0175H Masked by MR1 Mask Register 1 SPD M@NF[MR2]E SPD M@NF[MR1]E 0175H Masked by MR1 SPD M@NF[MR1]E 0175H Masked by MR1 Mem. at Next Free Addr. Step DM@NF[MR1]E 0175H Masked by MR1 Not Free Addr. Random SPD M@NF[MR1]E 0175H Masked by MR1 Not Free Addr. Step SPD M@NF[MR1]E 0175H Masked by MR1 Not Free Addr. Step SPD M@NF[MR1]E 0175H Masked by MR1 Not Free Addr. Step SPD M@NF[MR1]E 0175H Masked by MR1 Not Free Addr. Step SPD M@NF[MR1]E 0175H Masked by MR1 Not Free Addr. Step SPD M@NF[MR1]E 0175H Masked by MR1 Not Free Addr. Step SPD M@NF[MR1]E 0175H Masked by MR1 Not Free Addr. Step SPD M@NF[MR1]E 0175H Masked by MR1 Not Free Addr. Step SPD M@NAR[AR][MR1]E		-		Mana at Navit Erea Addr. Emply		010511
Instruction: Select Persistent Destination Masked by MR2 SPD M@NF[MR2]E 0155H Operation Mnemonic Op-Code Mem. at Next Free Addr., Skip SPD M@NF[MR2]E 0136H Masked by MR2 SPD CR[MR1] 0140H Masked by MR1 SPD M@NF[MR2]S 0136H Masked by MR2 SPD MR1 0100H Masked by MR1 SPD M@NF[MR2]S 0137H Masked by MR1 SPD M@(AR][MR1]V 0144H Masked by MR1 SPD M@(MR1]R 0137H Masked by MR1 SPD M@(AR][MR1]V 0144H Masked by MR2 SPD M@(MR1]R 0137H Masked by MR1 SPD M@(AR][MR1]V 0144H Masked by MR2 SPD M@(AR][R 0137H Masked by MR1 SPD M@(AR][MR1]Z 0164H Masked by MR2 SPD M@(AR][R 0128H Masked by MR2 SPD M@(AR][MR1]Z 0164H SPD M@(AR][MR1]Z 0164H Segment Control Register TCO C T 0220H Masked by MR1 SPD M@(AR][MR1]Z 0124H SPD M@(AR][MR1]Z 0124H SPD M@(AR][MR1]Z 0124H SPD M@(AR][MR1]Z 0124H	niem at highest hie materi	or onlightin	000011		- ,	
Instruction: Select Persistent Destination Mnemonic Op-Code Comparand Register SPD CR 0100H Masked by MR1 SPD CR 0100H Masked by MR1 SPD CR[MR1] 0140H Masked by MR1 SPD CR[MR1] 0140H Masked by MR2 SPD M@NF[MR1],S 0176H Mask Register 1 SPD M@NF[MR1],S 016H Masked by MR1 SPD M@[AR][MR1],V 016H Masked by MR1 SPD M@[AR][MR2],V 014H Masked by MR1 SPD M@[AR][MR2],V 014H Masked by MR1 SPD M@[AR][MR2],V 014H Mem. at Addr. Reg. set Valid SPD M@[AR][MR1],E 016H Masked by MR1 SPD M@[AR][MR1],E 016H Masked by MR1 SPD M@[AR][MR1],E 016H Masked by MR1 SPD M@[AR][MR1],S 016H Masked by MR1 SPD M@[AR][MR1],S 016H Masked by MR1 SPD M@[AR][MR1],S 012H Mem. at Addr. Reg. set Random SPD M@[AR][MR1],S 016H Masked by MR1 SPD M@[AR][MR1],S 016H Masked by MR1 SPD M@[AR][MR1],S 016H </td <td> </td> <td></td> <td></td> <td></td> <td></td> <td></td>						
Comparand Register Masked by MR1 SPD CR 0100H Masked by MR1 SPD CR[MR1] 0100H Masked by MR1 SPD CR[MR1] 0140H Masked by MR2 SPD M@NF[MR2].S 0186H Mask Register 1 SPD MR1 0109H Masked by MR1 SPD M@NF[MR2].S 0180H Mask Register 2 SPD MR2 0100H Masked by MR1 SPD M@NF[MR1].R 013H Mem. at Addr. Reg. set Valid SPD M@[AR][MR1].V 0164H Masked by MR1 SPD M@[AR][MR2].R 017H Masked by MR2 SPD M@[AR][MR1].V 0164H Masked by MR1 SPD M@[AR][MR2].R 017H Mem. at Addr. Reg. set Empty SPD M@[AR][MR2].E 012H Masked by MR1 SPD M@[AR][MR2].S 012H Mem. at Addr. Reg. set Skip SPD M@[AR][MR1].S 0166H Page Address Register TCO SC 021H Masked by MR1 SPD M@[AR][MR1].S 0164H 0164H Network Register TCO AR 0220H Masked by MR1 SPD M@[AR][MR1].R 0164H 0164H 0164H Network Register TCO AR 0220H Masked by MR1 SPD M@[AR][MR2].R 017H 0164H 0164H<	Instruction: Select Pers	istent Destination		WASKEU UY WINZ	ישיושיור[ויוח∠],⊏	
Masked by MR1 Masked by MR2SPD CR[MR1] SPD CR[MR2]0140H 0180HMasked by MR2SPD M@NF[MR2],S0186HMask Register 1 Mask Register 1 Mask Register 2 Masked by MR1SPD M@(NR] SPD M@(NR],V0184HMasked by MR1 SPD M@(NR],V0174H Masked by MR1Masked by MR1 SPD M@(NR],R0177H Masked by MR10177H Masked by MR20187HMem. at Addr. Reg. set Valid Masked by MR1SPD M@(AR][MR1],V0164HInstruction: Temporary Command Override OperationMnemonic Op-Code Control RegisterTCO CT0200HMem. at Addr. Reg. set Empty Masked by MR2SPD M@(AR][MR1],E SPD M@(AR][MR2],E0126HControl Register SPD M@(AR][MR2],S0126HAddress Register Read Next Free AddressTCO PA0228HMem. at Addr. Reg. set Random Masked by MR2SPD M@(AR][MR2],S0126HAddress Register NO ARTCO PA0228HMem. at Addr. Reg. set Random Masked by MR2SPD M@(AR][MR2],R SPD M@(AR][MR1],R SPD M@(AR][MR1],R0127H NO AR0127H0167HMemory at Address set Valid Masked by MR1 SPD M@(AR][MR1],R SPD M@(AR][MR1],R0127H NO AR0300HMemory at Address set Valid Masked by MR1 SPD M@(AR][MR1],R0924H SPD M@(AR][MR1],R0924H NO CR_[AR][MR1] SPD M@(AR][MR1],R0924H NO SPC M(MAR2Memory at Address Reg. MOV CR_[AR][MR1] SPD M@(AR][MR1],R0304H Masked by MR1 Masked by MR1 SPD M@(AR][MR1],S0924H SPD M@(AR][MR1],S0924H SPD M@(AR][MR2],R0924H SPD M@(AR][MR1],R0924H SPD M@(AR][MR2],R0924H SPD M@(AR][MR2],R<	Operation	Mnemonic C)p-Code	Mem. at Next Free Addr., Skip	SPD M@NF,S	0136H
Masked by MR2SPD CR[MR2]0180HMask Register 1SPD MR10108HMask Register 2SPD MR20110HMask Register 2SPD M@(AR][V012HMasked by MR1SPD M@(AR][V012HMasked by MR2SPD M@(AR][MR1],V016HMem. at Addr. Reg. set Empty Masked by MR1SPD M@(AR][MR2],E012FHMasked by MR1SPD M@(AR][MR1],E016HMem. at Addr. Reg. set Skip Masked by MR2SPD M@(AR][MR2],S012FHMem. at Addr. Reg. set Skip Masked by MR2SPD M@(AR][MR1],S016HMem. at Addr. Reg. set Skip Masked by MR2SPD M@(AR][MR1],S016HMem. at Addr. Reg. set Random Masked by MR1SPD M@(AR][MR1],S016HMem. at Addr. Reg. set Random Masked by MR1SPD M@(AR][MR1],R012FHMemory at Address set Valid Masked by MR1SPD M@(AR][MR1],R012FHMemory at Address set Valid Masked by MR1SPD M@(AR][MR1],R012FHMemory at Address set Valid Masked by MR1SPD M@(AR][MR1],R014HMemory at Address set Valid Masked by MR1SPD M@aaaH[MR1],E092HMemory at Address set Skip Masked by MR1SPD M@aaaaH[MR1],E092HMemory at Address set Skip Masked by MR2SPD M@aaaaH[MR1],E092HMemory at Address set Random Masked by MR2SPD M@aaaaH[MR1],E092HMemory at Address set Random Masked by MR2SPD M@aaaaH[MR1],E092HMemory at Address set Random Masked by MR2SPD M@aaaaH[MR1],E092HMemory at Address set	Comparand Register	SPDCR	0100H	Masked by MR1	SPD M@NF[MR1],S	0176H
Mask Register 1SPD MR1O108HMask Register 2SPD MR10104HMask Register 2SPD MR20110HMask Register 2SPD M@[AR],V0124HMasked by MR1SPD M@[AR],MR1],V0124HMasked by MR2SPD M@[AR],MR2],V0144HMasked by MR1SPD M@[AR],MR2],E0125HMasked by MR1SPD M@[AR],MR2],E015HMasked by MR2SPD M@[AR],MR2],E015HMasked by MR2SPD M@[AR],MR2],E016HMasked by MR2SPD M@[AR],MR2],S016HMasked by MR2SPD M@[AR],MR1],S016HMasked by MR2SPD M@[AR],MR1],R017HMasked by MR2SPD M@[AR],MR1],R017HMasked by MR2SPD M@[AR],MR1],R017HMasked by MR2SPD M@[AR],MR1],R017HMasked by MR2SPD M@[AR],MR2],R012HMemory at Address set ValidSPD M@aaaH,[MR2],VMasked by MR1SPD M@aaaH,[MR2],VMasked by MR1SPD M@aaaH,[MR2],CMasked by MR1SPD M@aaaH,[MR2],EMasked by MR1SPD M@aaaH,[MR2],CMasked by MR1SPD M@aaaH,[MR2],C <td>Masked by MR1</td> <td>SPD CR[MR1]</td> <td>0140H</td> <td>Masked by MR2</td> <td>SPD M@NF[MR2],S</td> <td>01B6H</td>	Masked by MR1	SPD CR[MR1]	0140H	Masked by MR2	SPD M@NF[MR2],S	01B6H
Mask Register 1SPD MR10108HMasked by MR1SPD M@NFIMR1I,R0177HMask Register 2SPD M@(AR],V0124HMasked by MR2SPD M@(AR],NV0124HMasked by MR2SPD M@(AR],MR1,V0164HMasked by MR2SPD M@(AR],MR1,V0164HMem. at Addr. Reg. set Empty Masked by MR2SPD M@(AR],MR1,E0165HMasked by MR2OP-CodeMem. at Addr. Reg. set Skip Masked by MR1SPD M@(AR],MR1,E0165HControl Register Reg. Set SR SPD M@(AR],MR1,S0125HControl Register Reg. Set SR SPD M@(AR],MR1,S0126HControl Register Reg. Set SR SPD M@(AR],MR1,S0126HNoNoCO0230HMemory at Address set Valid Masked by MR2SPD M@(AR],MR1,R SPD M@aaaH,[MR1,V0924H0127HNo<	Masked by MR2	SPD CR[MR2]	0180H			
Mask Register 2 SPD MP2 0110H Masked by MR2 SPD M@(AR](M 012H Mem. at Addr. Reg. set Valid SPD M@(AR][MR1],V 0164H Instruction: Temporary Command Override Masked by MR2 SPD M@(AR][MR1],V 0164H Instruction: Temporary Command Override Masked by MR2 SPD M@(AR][MR1],E 012H Operation Mnemonic Op-Code Masked by MR2 SPD M@(AR][MR1],E 0165H Control Register TCO CT 020H Masked by MR2 SPD M@(AR][MR1],E 0165H Segment Control Register TCO SC 021H Masked by MR2 SPD M@(AR][MR1],S 0164H Address Register TCO CC 020H Masked by MR2 SPD M@(AR][MR1],S 0164H Address Register TCO SC 021H Masked by MR2 SPD M@(AR][MR1],S 0164H Device Select Register TCO DS 0228H Mem. at Addr. Reg. set Random SPD M@(AR][MR1],R 012H Masked by MR1 SPD M@(AR][MR1],R 012H Masked by MR1 SPD M@(AR][MR1],R 014H No Operation MOV CR, MR1 030H Masked by MR1 SPD M@aaaH[MR1],E 094H Masked by MR1 MOV CR, IAR][MR1] 034H Masked by MR2 SPD M@aaaH[MR1],E 094H Masked by M				Mem. at Next Free Addr., Random	SPD M@NF,R	0137H
Mem. at Åddr. Reg. set Valid Masked by MR1 SPD M@[AR][V 0124H SPD M@[AR][MR1],V 0124H 0164H Instruction: Temporary Command Override Operation Mnemonic Op-Code Mem. at Addr. Reg. set Empty Masked by MR1 SPD M@[AR][MR2],E 0125H Control Register TCO CA 0200H Mem. at Addr. Reg. set Skip Masked by MR2 SPD M@[AR][MR2],E 0145H Segment Control Register TCO PA 0200H Mem. at Addr. Reg. set Skip Masked by MR2 SPD M@[AR][MR2],E 0145H Segment Control Register TCO AR 0228H Mem. at Addr. Reg. set Random Masked by MR2 SPD M@[AR][MR2],S 0126H Address Register TCO DS 0228H Mem. at Addr. Reg. set Random Masked by MR2 SPD M@[AR][MR2],R 0127H Noc Operation Moemory at Address set Valid Masked by MR1 SPD M@[AR][MR2],R 0127H Memory at Address set Valid Masked by MR2 SPD M@[AR][MR2],R 0924H Noc Operation NOP 0300H Memory at Address set Valid Masked by MR2 SPD M@[AaaaH[MR2],V 0924H Noc Operation NOV CR, IAR] 0304H Memory at Address set Skip Masked by MR1 SPD M@[AaaaH[MR1],E 0925H Moery at Address MOV CR, IAR] 0304H <td< td=""><td></td><td>SPD MR1</td><td>0108H</td><td>Masked by MR1</td><td>SPD M@NF[MR1],R</td><td>0177H</td></td<>		SPD MR1	0108H	Masked by MR1	SPD M@NF[MR1],R	0177H
Masked by MR1 Masked by MR2SPD M@[AR][MR1],V SPD M@[AR][MR2],V0164H 01A4HInstruction: Temporary Command Override OperationMnemonic MaemonicOp-Code Op-CodeMem. at Addr. Reg. set Empty Masked by MR2SPD M@[AR][MR1],E SPD M@[AR][MR1],E SPD M@[AR][MR2],E0125H 0165H Nasked by MR2Control Register SPD M@[AR][MR1],S 0166H Masked by MR1CO Control Register SPD M@[AR][MR1],S SPD M@[AR][MR2],S0126H 0165H Nasked by MR1 Masked by MR2SPD M@[AR][MR1],S SPD M@[AR][MR2],S0126H 0165H Nasked by MR1 Masked by MR2SPD M@[AR][MR2],S SPD M@[AR][MR2],S0126H 0166HControl Register Segment Control Register TCO NFCO NF 0220H Need Next Free Address Read Next Free Address Read Persistent Destination TCO PD0228H Read Persistent Destination TCO PD0228H Read Persistent Destination MOS CP CO PD0230HMemory at Address set Valid Masked by MR1 Masked by MR2SPD M@[AR][MR2],R SPD M@[AR][MR2],R0127H 01A7HInstruction: Data Move OperationMnemonic MOV CP, Co PS OgazaHOp-Code Comparand Register from: No OperationMov CR, IAR] MOV CR, IAR] Mov CR, IAR] Masked by MR1 Masked by MR2SPD M@[AaaH][MR2],R SPD M@[AaaH][MR2],E0924H 09A5HMemory at Address Reg. Mov CR, IAR] Masked by MR1 Masked by MR2MOV CR, IAR][MR1] SPD M@[AaaH][MR1],S SPD M@[AaaH][MR2],E0926H 09A5HMemory at Address set Skip Masked by MR1 Masked by MR2SPD M@[AaaH][MR1],S SPD M@[AaaH][MR1],S SPD M@[AaaH][MR1],S SPD M@[AaaH][MR1],S SPD M@[AaaH][MR1],S SPD M@[AaaH][MR1],S SPD M@[AaaH][MR1],S SPD M@[AaaH]	Mask Register 2	SPD MR2	0110H	Masked by MR2	SPD M@NF[MR2],R	01B7H
Masked by MR2SPD M@[AR][MR2],V01A4HOperationMnemonicOp-CodeMem. at Addr. Reg. set Empty Masked by MR2SPD M@[AR][MR1],E0165H0165HControl RegisterTCO PA0200HMasked by MR2SPD M@[AR][MR1],E0165H0165HControl RegisterTCO PA0200HMasked by MR1SPD M@[AR][MR2],E0145HControl RegisterTCO AR0220HMasked by MR1SPD M@[AR][MR1],S0166HControl RegisterTCO AR0220HMasked by MR2SPD M@[AR][MR2],S0146HRead Persistent SourceTCO DS0228HMasked by MR2SPD M@[AR][MR2],S0146HRead Persistent DestinationTCO PD0238HMem. at Addr. Reg. set Random Masked by MR1SPD M@[AR][MR2],S0147HInstruction: Data MoveOperationMov CR, MR1030HMasked by MR2SPD M@[AR][MR1],R0147H0167H0147HMasked Sister 1MOV CR, MR1030HMasked by MR1SPD M@aaaH[MR1],V0944H0964HMask Register 1MOV CR, MR1030HMasked by MR2SPD M@aaaH[MR1],E0965HMasked Sister 1MOV CR, IAR][MR2]0304HMasked by MR2SPD M@aaaH,[MR2],E0925HMasked Sister SReg.MOV CR, IAR][MR2]0334HMasked by MR2SPD M@aaaH,[MR2],E0936HMasked Sister SReg.MOV CR, IAR][MR2]0334HMasked by MR2SPD M@aaaH,[MR2],E0936HMasked Sister SReg.MOV CR, IAR][MR2]0334HMasked by MR2SPD M@aaaH,[MR2],E	Mem. at Addr. Reg. set Valid	SPD M@[AR],V	0124H			
Masked by MR2SPD M@(AR][MR2],V01A4HOperationMnemonicOp-CodeMem. at Addr. Reg. set Empty Masked by MR1SPD M@(AR][MR1],E0165HControl RegisterTCO CA0200HMasked by MR1SPD M@(AR][MR2],E01A5HPage Address RegisterTCO CA0200HMasked by MR2SPD M@(AR][MR2],E01A5HAddress RegisterTCO AR0220HMasked by MR1SPD M@(AR][MR2],S0126HAddress RegisterTCO AR0220HMasked by MR2SPD M@(AR][MR1],S0166HOticica RegisterTCO AR0220HMem. at Addr. Reg. set RandomSPD M@(AR][MR1],S0167H0167HMasked by MR1SPD M@(AR][MR1],R0127HMasked by MR2SPD M@(AR][MR1],R0167H0167H0167HMoerationNOP0300HMasked by MR1SPD M@(aaaH[MR1],V0964H0964HMoerationNOP0300HMasked by MR1SPD M@aaaH[MR1],V0964HMask Register 1MOV CR,IAR]0304HMasked by MR1SPD M@aaaaH[MR1],E0965HMasked by MR1MOV CR,IAR][MR2]0384HMemory at Address set SkipSPD M@aaaaH[MR1],E0965HMasked by MR1MOV CR,IAR][MR2]0384HMasked by MR2SPD M@aaaaH[MR1],E0966HMasked by MR1MOV CR,IAR][MR2]0384HMasked by MR2SPD M@aaaaH[MR1],S0926HMasked by MR1MOV CR,IAR][MR2]0384HMasked by MR2SPD M@aaaaH[MR1],S0966HMasked by MR1MOV CR,IAR][MR2]0384HMe	Masked by MR1	SPD M@[AR][MR1],V	0164H	Instruction: Temporary (Command Overr	ide
Mem. at Addr. Reg. set Empty Masked by MR1 SPD M@[AR][.E 0125H Control Register TCO CT 0200H Masked by MR2 SPD M@[AR][MR1],E 0165H SPD M@[AR][MR2],E 0145H Segment Control Register TCO AR 0220H Mem. at Addr. Reg. set Skip Masked by MR2 SPD M@[AR][MR1],S 0126H Address Register TCO AR 0220H Mem. at Addr. Reg. set Random Masked by MR2 SPD M@[AR][MR2],S 0146H Address Register TCO AR 0220H Mem. at Addr. Reg. set Random Masked by MR1 SPD M@[AR][MR2],S 0146H Read Persistent Source Read Persistent Destination TCO PD 0238H Memory at Address set Valid Masked by MR1 SPD M@[AR][MR1],R 0127H 0147H Instruction: Data Move Operation Mov CR, MR1 030H Memory at Address set Valid Masked by MR1 SPD M@aaaH[MR1],V 0924H 0964H Mov CR, MR1 030H Memory at Address set Skip Masked by MR1 SPD M@aaaH,[MR2],E 0925H Masked by MR1 MOV CR, [AR][MR2] 0304H Masked by MR2 SPD M@aaaH,[MR1],E 0966H Masked by MR1 MOV CR, [AR][MR2] 0304H Masked by MR2 SPD M@aaaaH,[MR1],E 0926H	Masked by MR2	SPD M@[AR][MR2],V	01A4H			
Mail at Addr. areg. set ExlipSPD M@(AR][MR1],EO125HMasked by MR2SPD M@(AR][MR1],E0165HMasked by MR2SPD M@(AR][MR1],S0165HMem. at Addr. Reg. set SkipSPD M@(AR][MR1],S0166HMasked by MR1SPD M@(AR][MR1],S0166HMasked by MR2SPD M@(AR][MR1],S0166HMasked by MR2SPD M@(AR][MR1],S0166HMem. at Addr. Reg. set RandomSPD M@(AR][MR1],R0127HMasked by MR1SPD M@(AR][MR1],R0127HMasked by MR2SPD M@(AR][MR1],R0127HMemory at Address set ValidSPD M@(AR][MR1],R0127HMemory at Address set ValidSPD M@(AR][MR1],R0127HMemory at Address set ValidSPD M@(AR][MR1],R0127HMemory at Addr. set EmptySPD M@(AR][MR1],E0924HMasked by MR2SPD M@(AR][MR1],E0924HMemory at Addr. set EmptySPD M@(aaaH[MR1],E0925HMasked by MR2SPD M@(aaaH[MR1],E0925HMemory at Address set SkipSPD M@(aaaH[MR2],SMemory at Address set SkipSPD M@(aaaH[MR2],SMemory at Address set SkipSPD M@(aaaH[MR1],SMemory at Address set RandomSPD M@(aaaH[MR1],RMem. at Highest-Prio. Match, VaidSPD M@(aaaH[MR1],R <td></td> <td></td> <td>010511</td> <td></td> <td></td> <td></td>			010511			
Masked by MR2SPD M@[AR][MR2],E01ASHSegment Control RegisterTCO SC0210HMasked by MR2SPD M@[AR][MR2],E01ASHNew Tree AddressTCO NF0218HMasked by MR1SPD M@[AR][MR2],S0126HAddress RegisterTCO DS0228HMasked by MR2SPD M@[AR][MR2],S016HDevice Select RegisterTCO DS0228HMem. at Addr. Reg. set RandomSPD M@[AR][MR1],R0127HDiffDiffDiffDiffMasked by MR2SPD M@[AR][MR2],R0127HDiffDiffDiffDiffDiffDiffMasked by MR2SPD M@[AR][MR2],R0127HDiff<						
Masked by MR2SPD M@(AR); SO1ACHRead Next Free AddressTCO NF0218HMem. at Addr. Reg. set Skip Masked by MR2SPD M@(AR); S0126HAddress RegisterTCO AR0220HMem. at Addr. Reg. set Random Masked by MR1SPD M@(AR); MR2], S01ACHRead Persistent SourceTCO PS0230HMem. at Addr. Reg. set Random Masked by MR1SPD M@(AR); MR2], R0127HNeather Step M@(AR); MR2], R0127HNeather Step M@(AR); MR2], R0127HMemory at Address set Valid Masked by MR2SPD M@(AR); MR2], R0127H0167HNetrotion: Data MoveOperationMnemonicOp-CodeMemory at Address set Valid Masked by MR2SPD M@(aaaH, W0944H0964HMov CR, MR10301HMov CR, MR20302HMemory at Address set Valid Masked by MR2SPD M@(aaaH, MR1], E0925HMemory at Address Reg.MOV CR, IAR]0304HMemory at Address set Skip Masked by MR2SPD M@(aaaH, MR1], E0965HMemory at Address Reg.MOV CR, IAR]0304HMemory at Address set Skip Masked by MR2SPD M@(aaaH, R), SPD M@(aaaaH, R), SPD M@(aaaaH, IMR1], E0966HMemory at AddressMOV CR, IAR]0304HMem. at Address set Random Masked by MR1 Masked by MR2SPD M@(aaaaH, R), SPD M@(aaaaH, R)						
Mem. at Addr. Reg. set Skip Masked by MR1 Masked by MR2SPD M@[AR][MR1],S SPD M@[AR][MR2],S0126H 01A6HAddress RegisterTCO AR Device Select Register0220H TCO DSMem. at Addr. Reg. set Random Masked by MR2SPD M@[AR][MR1],R SPD M@[AR][MR2],R0127H 01A6H0127H 01A7H0127H 0167H 01A7H0127H 0167H 01A7H0127H 0167H 01A7H0127H 0167H 01A7H0127H 0167H 01A7H0127H 0167H 01A7H0127H 0167H 01A7H0127H 0167H 01A7H0127H 0167H 01A7H0127H 0167H 01A7H0127H 0167H 01A7H0127H 0167H 01A7H0127H 0167H 01A7H0127H 0167H 0147H0127H 0167H 0147H0127H 0167H 0147H0127H 0167H 0147H0127H 0167H 0147H0127H 0167H 0147H0127H 0167H 0147H0127H 0167H 0147H0127H 0167H 0167H 0147H0127H 0167H 0147H0127H 0167H 0147H0127H 0167H 0147H0127H 0167H 0147H0127H 0167H 0147H0127H 0167H 0147H0127H 0167H 0167H 0147H0127H 0167H0127H 0167H 0167H 0167H0127H 0167H 0167H0127H 0167H0127H 0167H 0167H 0167H0127H 0167H 0167H 0167H0127H 0167H 0167H 0167H0127H 0167H 0167H0127H 0167H0127H 0167H 0167H0127H 0167H 0167H 0167H0127H 0167H0127H 0167H 0167H 0167H0127H 0167H 0167H 0167H 0167H 0167H 0167H0127H 0167H 0167H 0167H 0167H 0167H 0167H 0167H0127H <b< td=""><td>Masked by MR2</td><td>SPD M@[AR][MR2],E</td><td>UTASH</td><td></td><td></td><td></td></b<>	Masked by MR2	SPD M@[AR][MR2],E	UTASH			
Minimit ar Addr. Rigg. self and/pShi D Megratij, DO120HDevice Select RegisterTCO DS0228HMasked by MR1 Masked by MR2SPD M@[AR][MR1],S016H0162HDevice Select RegisterTCO PS0230HMem. at Addr. Reg. set Random Masked by MR1 Masked by MR2SPD M@[AR][MR1],R0127H0162HDevice Select RegisterTCO PD0238HMemory at Address set Valid Masked by MR2SPD M@[AR][MR2],R0147H0167HDevice Select RegisterTCO PD0230HMemory at Address set Valid Masked by MR2SPD M@[AR][MR2],R0147H0167HDevice Select Register from: No OperationNOP0300HMemory at Address set Valid Masked by MR2SPD M@aaaH[MR2],V094HMov CR, MR10301HMemory at Address set Skip Masked by MR2SPD M@aaaaH[MR2],E0925HMov CR, IAR]0304HMemory at Address set Skip Masked by MR2SPD M@aaaaH[MR2],E094HMasked by MR1MOV CR, IAR][MR1]0344HMasked by MR2SPD M@aaaaH[MR2],E094HMemory at AddressMOV CR, IAR][MR1]034HMemory at Address set Skip Masked by MR2SPD M@aaaaH[MR1],S096HMasked by MR1MOV CR, aaaaH0B04HMasked by MR2SPD M@aaaaH[MR1],R097HMasked by MR1MOV CR, aaaaH0B04HMasked by MR2SPD M@aaaaH[MR1],R0927HMemory at AddressMOV CR, HM0305HMasked by MR2SPD M@aaaaH[MR2],R0927HMasked by MR1MOV CR, HM0305HMasked by MR2SPD	Mam at Addr. Bag. sat Skip	SDD WOLDE	0126			
Masked by MR2SPD M@[AR][MR2],S01A6HRead Persistent Šource Read Persistent DestinationTCO PS0230HMem. at Addr. Reg. set Random Masked by MR1SPD M@[AR][MR1],R SPD M@[AR][MR2],R0127H 0167H0127H 0167H0127H 0167H0127H 0167H0127H 0167H0127H 0167HMemory at Address set Valid Masked by MR2SPD M@aaaH,[W SPD M@aaaH,[W SPD M@aaaH,[MR2],V0924H SPD M@aaaH[MR2],V0924H 0964HNOP 0300H Masked by MR1Memory at Address set Valid Masked by MR2SPD M@aaaH,[MR2],V0924H SPD M@aaaH,[MR2],V0944H SPD M@aaaH,[MR2],VNOP0300H Masked by MR1Memory at Address set Skip Masked by MR1 Masked by MR2SPD M@aaaH,[MR2],E0925H SPD M@aaaH,[MR2],E0926H SPD M@aaaH,[MR2],SMemory at Address SPD M@aaaH,[MR2],S0926H SPD M@aaaH,[MR2],SMemory at Address Mov CR,[AR][MR2]Mov CR,[AR][MR2]0384HMem. at Address set Random Masked by MR1 Masked by MR2SPD M@aaaH,[MR1],S SPD M@aaaH,[MR2],S0926H SPD M@aaaH,[MR2],SMemory at Address MOV CR,aaaH Masked by MR2MOV CR,aaaH MOV CR,aaaH[MR1]0804H Masked by MR2Mem. at Address set Random Masked by MR1 Masked by MR1 Masked by MR2SPD M@aaaH,[MR1],R SPD M@aaaaH,[MR2],R0927H O97HMem. at Highest-Prio. Match Mov CR,HM[MR2]MOV CR,HM MOV CR,HM[MR2]0385HMem. at Highest-Prio. Match, ValidSPD M@aaaH,[MR2],R SPD M@aaaH,[MR2],R0927H O97HMem. at Highest-Prio. Match Mov CR,HM[MR2]MOV CR,HM[MR2] O385H					TCO DS	
Mem. at Addr. Reg. set Random Masked by MR1 Masked by MR2SPD M@[AR][MR1],R SPD M@[AR][MR2],R0127H 0167H 01A7H0127H 0167H 01A7H0127H 0167H 01A7HInstruction: Data Move OperationMnemonic Comparand Register from: No OperationOp-CodeMemory at Address set Valid Masked by MR2SPD M@aaaH[MR1],V SPD M@aaaH[MR2],V0924H 0944HNOP 0944H0300H Mask Register 1NOP MOV CR,MR10300H Mov CR,MR1Memory at Addr. set Empty Masked by MR2SPD M@aaaH[MR1],E SPD M@aaaH[MR2],E0925H 0945H0925H 0945H0925H Masked by MR1 Masked by MR20920H M@aaaH[MR1],E 0945HMov CR,[AR] 0930H0304H Mov CR,[AR][MR1]Memory at Address set Skip Masked by MR2SPD M@aaaH[MR1],S SPD M@aaaH[MR2],S0926H 0946HMemory at Address Memory at AddressMOV CR,[AR][MR2] Mov CR,[AR][MR2]0384HMem. at Address set Random Masked by MR1 Masked by MR2SPD M@aaaH,R SPD M@aaaH[MR2],S0926H 0946HMemory at Address Memory at AddressMOV CR,aaaH MOV CR,aaaH[MR2] 0936HMemory at Address Mov CR,aaaH[MR2] 0936HMov CR,aaaH[MR2] 0936H0304H Masked by MR1 Masked by MR1 Masked by MR20304H MOV CR,aaaH[MR2] 0936HMem. at Address set Random Masked by MR2SPD M@aaaH,R SPD M@aaaH[MR2],R0927H 0927H 0947HMem. at Highest-Prio. Match Masked by MR1 Masked by MR2MOV CR,HM[MR1] 0335HMem. at Highest-Prio. Match, VaidSPD M@hmaaaH[MR2],R0927H 0947HMem. at Highest-Prio. Match Masked by MR2MOV CR,HM[MR1] 0335H <br< td=""><td></td><td></td><td></td><td></td><td>TCO PS</td><td>0230H</td></br<>					TCO PS	0230H
Masked by MR1 Masked by MR2SPD M@[AR][MR1],R SPD M@[AR][MR2],R0167H 01A7HInstruction: Data Move OperationMnemonic Op-CodeMemory at Address set Valid Masked by MR1 Masked by MR2SPD M@aaaH[MR1],V SPD M@aaaH[MR2],V0924H 0964HOperationNOP0300H Mask Register from: No OperationMemory at Addr. set Empty Masked by MR1 Masked by MR2SPD M@aaaH[MR2],V SPD M@aaaH[MR1],E SPD M@aaaH[MR2],E0925H 0925H 0965H0925H 0965HMOV CR, [AR] Memory at Address Reg. MOV CR, [AR][MR1] 0344H Masked by MR1 Masked by MR2SPD M@aaaH[MR1],E SPD M@aaaH[MR1],S SPD M@aaaH[MR2],S0926H 0965HMemory at Address Reg. 0965HMOV CR, [AR][MR2] 0384H0304H Mov CR, [AR][MR2]Memory at Address set Skip Masked by MR2SPD M@aaaH,S SPD M@aaaH[MR1],S SPD M@aaaH[MR2],S0926H 0966H 0966HMemory at Address Mow CR, [AR][MR2]MOV CR, [AR][MR2] 0384HMem. at Address set Random Masked by MR2SPD M@aaaH[MR1],R SPD M@aaaH[MR2],R0927H 0967H 0967HMem. at Highest-Prio. Match Masked by MR1 Masked by MR1 Masked by MR2MOV CR, HM (MR1] 0305H0305HMem. at Highest-Prio. Match, ValidSPD M@aaaH[MR1],R SPD M@aaaH[MR2],R0927H 0967HMem. at Highest-Prio. Match, Mov CR, HM (MR1] 0345H Masked by MR20305HMem. at Highest-Prio. Match, ValidSPD M@aaaH[MR2],R SPD M@aaaH[MR2],R0927H 0967HMem. at Highest-Prio. Match, Mov CR, HM (MR1] 0345H Masked by MR20305H	Masked by Miliz		UIAUIT	Read Persistent Destination	TCO PD	0238H
Masked by MR2SPD M@[AR][MR2],RO1A7HOperationMnemonicOp-CodeMemory at Address set Valid Masked by MR1 Masked by MR2SPD M@aaaH,V0924HOperationNOP0300HMemory at Address set Empty Masked by MR2SPD M@aaaH[MR2],V0944HMov CR,MR10301HMemory at Addr. set Empty Masked by MR2SPD M@aaaH,E SPD M@aaaH[MR1],E SPD M@aaaH[MR2],E0925H0965HMov CR,[AR] Masked by MR1 Masked by MR20304HMemory at Address set Skip Masked by MR2SPD M@aaaH[MR2],E SPD M@aaaH[MR2],S0926HMemory at Address Masked by MR2MOV CR,[AR][MR2] Masked by MR20304HMemory at Address set Skip Masked by MR2SPD M@aaaH[MR1],S SPD M@aaaH[MR2],S0926HMemory at Address Masked by MR2MOV CR,[AR][MR2] Mov CR,[AR][MR2]0304HMem. at Address set Random Masked by MR2SPD M@aaaH[MR1],R SPD M@aaaH[MR2],R0927H O927HMem. at Highest-Prio. Match Masked by MR1MOV CR,HM MOV CR,HM[MR2]0305HMem. at Highest-Prio. Match, ValidSPD M@aaaH[MR2],R SPD M@aaaH[MR2],R0927H O9A7HMem. at Highest-Prio. Match Masked by MR1 Masked by MR2MOV CR,HM MOV CR,HM[MR1]0305H MOV CR,HM[MR2]Mem. at Highest-Prio. Match, ValidSPD M@htth,V012CHMem. at Highest-Prio. Match Mov CR,HM[MR2]0385H	Mem. at Addr. Reg. set Random	SPD M@[AR],R	0127H	La stantistica Data Maria		
Memory at Address set Valid Masked by MR1 Masked by MR2SPD M@aaaH,V SPD M@aaaH[MR1],V SPD M@aaaH[MR2],V0924H 0964H 09A4HComparand Register from: No OperationNOP Mov CR,MR1 Mask Register 20300H Mov CR,MR1 Mov CR,MR2Memory at Addr. set Empty Masked by MR2SPD M@aaaH,E SPD M@aaaH[MR1],E SPD M@aaaH[MR2],E0925H 0945HMov CR,IAR] Masked by MR1 Masked by MR20304H Mov CR,IAR]0304H Mov CR,IAR]Memory at Address set Skip Masked by MR2SPD M@aaaH[MR2],E SPD M@aaaH[MR2],E0926H 09A5HMemory at Address 09A5HMOV CR,IAR][MR2] 0384H0304H Mov CR,IAR][MR2]Memory at Address set Skip Masked by MR2SPD M@aaaH[MR2],S SPD M@aaaH[MR2],S0926H 09A6HMemory at Address Mov CR,IAR][MR2]Memory at Address Mov CR,IAR][MR2]Mov CR,aaaH 0804H Mov CR,aaaH[MR2]0804H Masked by MR1 Masked by MR2Mem. at Address set Random Masked by MR2SPD M@aaaH[MR2],R SPD M@aaaH[MR2],R0927H 09A7HMem. at Highest-Prio. Match Masked by MR1 Masked by MR2MOV CR,HM MOV CR,HM[MR1] 0305H MOV CR,HM[MR2]0305H 0305HMem. at Highest-Prio. Match, ValidSPD M@aaaH[MR2],R 09A7H0927H 09A7HMem. at Highest-Prio. Match Masked by MR2MOV CR,HM[MR1] 0305H MOV CR,HM[MR2]0305H 0385H	Masked by MR1	SPD M@[AR][MR1],R	0167H			
Memory at Address set Valid Masked by MR1 Masked by MR2SPD M@aaaH,V SPD M@aaaH[MR1],V SPD M@aaaH[MR2],V0924H 0964H 09A4HNo OperationNOP Mask Register 10300H Mask Register 2Memory at Addr. set Empty Masked by MR1 Masked by MR2SPD M@aaaH[MR2],V SPD M@aaaH[MR2],E0925H 0965H 0965H 0965HNo Operation Masked by MR1 Masked by MR2SPD M@aaaH[MR1],E SPD M@aaaH[MR2],E0925H 0965HNo Operation Masked by MR1 Masked by MR2MOV CR,IAR] MOV CR,IAR] MOV CR,IAR]0304H Masked by MR1 Mov CR,IAR][MR1]0344H Masked by MR2Memory at Address set Skip Masked by MR2SPD M@aaaH[MR2],E SPD M@aaaH[MR2],S0926H 09A5HMemory at Address Memory at AddressMOV CR,aaaH MOV CR,aaaH[MR1] 0B44H Masked by MR20804HMem. at Address set Random Masked by MR2SPD M@aaaH[MR1],R SPD M@aaaH[MR2],R0927H 09A7HMem. at Highest-Prio. Match Masked by MR1 Masked by MR2MOV CR,HM MOV CR,HM[MR1] 0345H MOV CR,HM[MR2]0305H 0304HMem. at Highest-Prio. Match, ValidSPD M@aaaH[MR2],R SPD M@aaaH[MR2],R09A7HMem. at Highest-Prio. Match Masked by MR2MOV CR,HM[MR1] MOV CR,HM[MR2]0305H 0385HMem. at Highest-Prio. Match, ValidSPD M@aaaH[MR2],R09A7HMem. at Highest-Prio. Match Masked by MR2MOV CR,HM[MR2] MOV CR,HM[MR2]0385H	Masked by MR2	SPD M@[AR][MR2],R	01A7H	Operation	Mnemonic	Op-Code
Masked by MR1 Masked by MR2SPD M@aaaH[MR1],V SPD M@aaaH[MR2],V0964H 09A4HMov CR,MR1 0301H0301H Mask Register 1Memory at Addr. set Empty Masked by MR1 Masked by MR2SPD M@aaaH,E SPD M@aaaH[MR1],E SPD M@aaaH[MR2],E0925H 0945HMemory at Address Reg. 0945HMOV CR,[AR] Mov CR,[AR][MR1] 034H0304H Masked by MR1 Mov CR,[AR][MR1]0304H 0304HMemory at Address set Skip Masked by MR1 Masked by MR2SPD M@aaaH,S SPD M@aaaH[MR1],S SPD M@aaaH[MR2],S0926H 0946HMemory at Address Memory at AddressMOV CR,[AR][MR2] 0384H0304H Mov CR,[AR][MR2]Memory at Address set Skip Masked by MR2SPD M@aaaH[MR1],S SPD M@aaaH[MR2],S0926H 0966HMemory at Address Mov CR,[AR][MR2]Mov CR,[AR][MR2] 0384HMem. at Address set Random Masked by MR2SPD M@aaaH[MR1],R SPD M@aaaH[MR2],R0927H 09A7HMem. at Highest-Prio. Match Masked by MR1 Masked by MR2MOV CR,HM MOV CR,HM[MR2]0305H 0345HMem. at Highest-Prio. Match, ValidSPD M@aaaH[MR2],R SPD M@aaaH[MR2],R0927H 09A7HMem. at Highest-Prio. Match Masked by MR2MOV CR,HM[MR1] 0345H MOV CR,HM[MR2]0305H 0345H				Comparand Register from:		
Masked by MR2SPD M@aaaH[MR2],V09A4HMask Hegister 1MOV CR,MR20302HMemory at Addr. set Empty Masked by MR1 Masked by MR2SPD M@aaaH,E0925HMOV CR,[AR]0304HMemory at Address set Skip Masked by MR1SPD M@aaaH[MR1],E0965HMov CR,[AR][MR2]0344HMemory at Address set Skip Masked by MR1SPD M@aaaH[MR1],S0966HMemory at AddressMOV CR,[AR][MR2]0384HMemory at Address set Skip Masked by MR1SPD M@aaaH[MR1],S0926HMemory at AddressMOV CR,aaaH0B04HMem. at Address set Random Masked by MR1SPD M@aaaH[MR2],S09A6HMemory at AddressMOV CR,aaaH[MR1]0B44HMem. at Address set Random Masked by MR2SPD M@aaaH[MR1],R0927HMem. at Highest-Prio. MatchMOV CR,HM0305HMem. at Highest-Prio. Match, ValidSPD M@aaaH[MR2],R09A7HMem. at Highest-Prio. Match, ValidMOV CR,HM[MR2]0385H				No Operation	NOP	
Memory at Addr. set Empty Masked by MR1 Masked by MR2SPD M@aaaH,E SPD M@aaaH[MR1],E SPD M@aaaH[MR2],E0925H 0965H 09A5HMemory at Address Reg. Masked by MR1 Masked by MR2MOV CR,[AR] MOV CR,[AR][MR1] 0344H MOV CR,[AR][MR2]0304H 0344HMemory at Address set Skip Masked by MR2SPD M@aaaH[MR1],E SPD M@aaaH[MR1],S SPD M@aaaH[MR1],S SPD M@aaaH[MR2],S0926H 0966H 0966HMemory at Address Memory at AddressMOV CR,[AR][MR2] 0384H0304HMemory at Address set Skip Masked by MR2SPD M@aaaH[MR1],S SPD M@aaaH[MR2],S0926H 09A6HMemory at Address Masked by MR1 Masked by MR2MOV CR,aaaH MOV CR,aaaH[MR1] 0B44H Masked by MR20804HMem. at Address set Random Masked by MR2SPD M@aaaH,R SPD M@aaaH[MR2],R0927H 09A7HMem. at Highest-Prio. Match Masked by MR2MOV CR,HM MOV CR,HM[MR1] 0345H MOV CR,HM[MR2]0305H 0385HMem. at Highest-Prio. Match, ValidSPD M@aaaH[MR2],R0927H 09A7HMem. at Highest-Prio. Match Masked by MR2MOV CR,HM[MR1] 035H MOV CR,HM[MR2]0305H 0365H				Mask Register 1	MOV CR,MR1	0301H
Memory at Addr. set Empty Masked by MR1SPD M@aaaH,E0925H 0965HMasked by MR1MOV CR,[AR][MR1]0344H 0384HMasked by MR2SPD M@aaaH[MR1],E0965H 09A5HMasked by MR2MOV CR,[AR][MR2]0384HMemory at Address set Skip Masked by MR1SPD M@aaaH[MR1],S0926H 0966HMemory at AddressMOV CR,[AR][MR2]0384HMemory at Address set Skip Masked by MR1SPD M@aaaH[MR1],S0926H 0966HMemory at AddressMOV CR,aaaH0B04H Masked by MR10B44H Masked by MR20B44HMem. at Address set Random Masked by MR1SPD M@aaaH[MR2],S09A6HMem. at Highest-Prio. MatchMOV CR,aaaH[MR1] Masked by MR10305H MOV CR,aaaH[MR2]0305H Masked by MR2Mem. at Highest-Prio. Match, ValidSPD M@aaaH[MR2],R09A7HMem. at Highest-Prio. Match, Valid0305H Masked by MR2MOV CR,HM[MR2]0385HMem. at Highest-Prio. Match, ValidSPD M@aaaH[MR2],R09A7HMasked by MR2MOV CR,HM[MR2]0385H	Masked by MR2	SPD M@aaaH[MR2],V	09A4H	Mask Register 2	MOV CR,MR2	
Masked by MR1 Masked by MR2SPD M@aaaH[MR1],E SPD M@aaaH[MR2],E0965H 09A5HMasked by MR2MOV CR,[AR][MR2]0384HMemory at Address set Skip Masked by MR1 Masked by MR2SPD M@aaaH[MR2],E0926H 0966HMemory at AddressMOV CR,aaaH0B04H 0B44HMem. at Address set Random Masked by MR2SPD M@aaaH[MR2],S0966H 09A6HMem. at Highest-Prio. Match, ValidSPD M@aaaH[MR1],R SPD M@aaaH[MR2],R0927H 09A7HMem. at Highest-Prio. Match, ValidMOV CR,HM MOV CR,HM[MR2]0305H 0385HMem. at Highest-Prio. Match, ValidSPD M@aaaH[MR2],R SPD M@aaaH[MR2],R0927H 09A7HMem. at Highest-Prio. Match Masked by MR2MOV CR,HM MOV CR,HM[MR2]0305H 0385H				Memory at Address Reg.	MOV CR,[AR]	
Masked by MR2SPD M@aaaH[MR2],E09A5HMasked by MR2MOV CR,[AA][MR2]0304HMemory at Address set Skip Masked by MR1 Masked by MR2SPD M@aaaH[MR1],S0926HMemory at AddressMOV CR,aaaH0B04HMasked by MR1 Masked by MR2SPD M@aaaH[MR1],S0966HMasked by MR1MOV CR,aaaH[MR1]0B44HMem. at Address set Random Masked by MR1SPD M@aaaH[MR2],S09A6HMasked by MR2MOV CR,aaaH[MR2]0B84HMem. at Address set Random Masked by MR1 Masked by MR2SPD M@aaaH[MR1],R0927H 0967HMem. at Highest-Prio. Match Masked by MR1MOV CR,HM MOV CR,HM[MR1]0305H 0345HMem. at Highest-Prio. Match, ValidSPD M@aaaH[MR2],R09A7HMem. at Highest-Prio. Match Masked by MR2MOV CR,HM[MR2]0385H		- ,		Masked by MR1	MOV CR, [AR] [MR1]	0344H
Memory at Address set Skip Masked by MR1 SPD M@aaaH,S 0926H Memory at Address MOV CR,aaaH 0B04H Masked by MR1 SPD M@aaaH[MR1],S 0966H Masked by MR1 MOV CR,aaaH 0B44H Mem. at Address set Random Masked by MR2 SPD M@aaaH[MR2],S 09A6H Masked by MR2 MOV CR,aaaH[MR2] 0B44H Mem. at Address set Random Masked by MR1 SPD M@aaaH,R 0927H Mem. at Highest-Prio. Match MOV CR,HM 0305H Masked by MR2 SPD M@aaaH[MR1],R 0967H 09A7H Mem. at Highest-Prio. Match MOV CR,HM[MR2] 0385H Mem. at Highest-Prio. Match, Valid SPD M@aaaH[MR2],R 09A7H Masked by MR2 MOV CR,HM[MR2] 0385H				Masked by MR2	MOV CR, [AR] [MR2]	0384H
Masked by MR1 Masked by MR2SPD M@aaaH[MR1],S SPD M@aaaH[MR2],S0966H 09A6HMasked by MR1 Masked by MR2MOV CR,aaaH[MR1] 0B44H MOV CR,aaaH[MR2]0B44H 0B84HMem. at Address set Random Masked by MR1 Masked by MR1 	Masked by MR2	SFD IVI@aaan[IVIH2],E	USASH			
Masked by MR2 SPD M@aaaH[MR2],S 09A6H Masked by MR2 MOV CR,aaaH[MR2] 0B84H Mem. at Address set Random Masked by MR1 SPD M@aaaH,R 0927H Mem. at Highest-Prio. Match MOV CR,HM 0305H Masked by MR2 SPD M@aaaH[MR1],R 0967H Masked by MR1 MOV CR,HM[MR1] 0305H Masked by MR2 SPD M@aaaH[MR2],R 09A7H Masked by MR2 MOV CR,HM[MR1] 0345H Mem. at Highest-Prio. Match, Valid SPD M@aaaH[MR2],R 09A7H Masked by MR2 MOV CR,HM[MR2] 0385H	Memory at Address set Skip	SPD M@aaaH,S	0926H	Memory at Address		
Masked by MR2 SPD M@aaaH[MR2],S 09A6H Masked by MR2 MOV CR,aaaH[MR2] 0B84H Mem. at Address set Random Masked by MR1 SPD M@aaaH,R 0927H Mem. at Highest-Prio. Match MOV CR,HM 0305H Masked by MR2 SPD M@aaaH[MR1],R 0967H Masked by MR1 MOV CR,HM[MR1] 0305H Masked by MR2 SPD M@aaaH[MR2],R 09A7H Masked by MR2 MOV CR,HM[MR1] 0345H Mem. at Highest-Prio. Match, Valid SPD M@aaaH[MR2],R 09A7H Masked by MR2 MOV CR,HM[MR2] 0385H			0966H	Masked by MR1	MOV CR,aaaH[MR1]	0B44H
Masked by MR1 SPD M@aaaH[MR1],R 0967H Masked by MR1 MOV CR,HM[MR1] 0345H Masked by MR2 SPD M@aaaH[MR2],R 09A7H Masked by MR2 MOV CR,HM[MR2] 0385H Mem. at Highest-Prio. Match, Valid SPD M@HM,V 012CH 012CH 012CH				-		
Masked by MR1 SPD M@aaaH[MR1],R 0967H Masked by MR1 MOV CR,HM[MR1] 0345H Masked by MR2 SPD M@aaaH[MR2],R 09A7H Masked by MR2 MOV CR,HM[MR2] 0385H Mem. at Highest-Prio. Match, Valid SPD M@HM,V 012CH 012CH 012CH	Mem at Address set Pandem	SPD M@aaaH P	002711	Mom at Linhast Duis Matte		000511
Masked by MR2 SPD M@aaaH[MR2],R 09A7H Masked by MR2 MOV CR,HM[MR2] 0385H Mem. at Highest-Prio. Match, Valid SPD M@HM,V 012CH						
Mem. at Highest-Prio. Match, Valid SPD M@HM,V 012CH	-			· · ·		
	IVIASTED BY IVINZ		054/1	Wasked by WH2		0385H
	Mem at Highest-Prio Match Valid	SPD M@HM V	012CH			
	Masked by MR1	SPD M@HM[MR1],V	012CH			
Masked by MR2 SPD M@HM[MR2],V 01ACH						
				1		

INSTRUCTION SET SUMMARY Continued

Instruction: Data Move (Continued				
Operation		Op-Code	Memory at Next Free Address,	No Change to Validity	/ bits, from:
Mask Register 1 from:		-b-oone	Comparand Register	MOV NF, CR	0330H
U.S. Contraction of the second		0308H	Masked byMR1	MOV NF, CR[MR1]	0370H
Comparand Register No Operation	MOVMR1,CR NOP	0308H 0309H	Masked by MR2	MOV NF, CR[MR2]	03B0H
	MOV MR1, MR2	0309H 030AH	Mask Register 1	MOV NF, MR1	0331H
Mask Register 2			Mask Register 2	MOV NF, MR2	0332H
Memory at Address Reg.	MOV MR1,[AR]	030CH 0B0CH	-		
Memory at Address	MOV MR1,aaaH		Memory at Next Free Address,	Location set Valid, fr	om:
Mem. at Highest-Prio. Match		030DH	Comparand Register	MOV NF,CR,V	0334H
			Masked by MR1	MOV NF, CR[MR1], V	0374H
Mask Register 2 from:			Masked by MR2	MOV NF, CR[MR2], V	03B4H
Comparand Register	MOV MR2,CR	0310H	Mask Register 1	MOV NF, MR1, V	0335H
Mask Register 1	MOV MR2,MR1	0311H	Mask Register 2	MOV NF,MR2,V	0336H
No Operation	NOP	0312H	-		
Memory at Address Reg.	MOV MR2,[AR]	0314H	Instruction: Validity Bit (Control	
Memory at Address	MOV MR2,aaaH	0B14H			On Code
Mem. at Highest-Prio. Match	MOV MR2,HM	0315H	Operation	Mnemonic	Op-Code
			Set Validity bits at Address Re		
Memory at Address Register, N	•	oits, from:	Set Valid	VBC [AR],V	0424H
Comparand Register	MOV [AR],CR	0320H	Set Empty	VBC [AR],E	0425H
Masked by MR1	MOV [AR],CR[MR1]	0360H	Set Skip	VBC [AR],S	0426H
Masked byMR2	MOV [AR],CR[MR2]	03A0H	Set Random Access	VBC [AR],R	0427H
Mask Register 1	MOV [AR],MR1	0321H			
Mask Register 2	MOV [AR],MR2	0322H	Set Validity bits at Address		
			Set Valid	VBC aaaH,V	0C24H
Memory at Address Register, L	_ocation set Valid, from	n:	Set Empty	VBC aaaH,E	0C25H
Comparand Register	MOV [AR],CR,V	0324H	Set Skip	VBC aaaH,S	0C26H
Masked by MR1	MOV [AR],CR[MR1],V	/ 0364H	Set Random Access	VBC aaaH,R	0C27H
Masked byMR2	MOV [AR],CR[MR2],V	/ 03A4H			
Mask Register 1	MOV [AR],MR1,V	0325H	Set Validity bits at Highest-Prio	· · · · · · · · · · · · · · · · · · ·	
Mask Register 2	MOV [AR],MR2,V	0326H	Set Valid	VBC HM,V	042CH
			Set Empty	VBC HM,E	042DH
Memory at Address, No Chang	e to Validity bits, from	:	Set Skip	VBC HM,S	042EH
Comparand Register	MOV aaaH,CR	0B20H	Set Random Access	VBC HM,R	042FH
Masked byMR1	MOV aaaH,CR[MR1]	0B60H			
Masked by MR2	MOV aaaH,CR[MR2]	OBAOH	Set Validity bits at All Matching		0.400
Mask Register 1	MOV aaaH,MR1	0B21H	Set Valid	VBC ALM,V	043CH
Mask Register 2	MOV aaaH,MR2	0B22H	Set Empty	VBC ALM,E	043DH
			Set Skip	VBC ALM,S	043EH
Memory at Address, Location s	set Valid, from:		Set Random Access	VBC ALM,R	043FH
Comparand Register	MOV aaaH,CR,V	0B24H			
Masked by MR1	MOV aaaH,CR[MR1],	V 0B64H	Instruction: Compare		
Masked by MR2	MOV aaaH,CR[MR2],	V 0BA4H	Operation	Mnemonic	Op-Code
Mask Register 1	MOV aaaH,MR1,V	0B25H	Compare Valid Locations	CMP V	0504H
Mask Register 2	MOV aaaH,MR2,V	0B26H	Compare Empty Locations	CMPE	0505H
_			Compare Skipped Locations	CMPS	0506H
Memory at Highest-Priority Ma from:	atch, No Change to Va	alidity bits,	Comp. Random Access Locations		0507H
Comparand Register	MOV HM,CR	0328H	Instruction: Special Inst	ructions	
Masked by MR1	MOV HM, CR[MR1]	0368H	Operation	Mnemonic	Op-Code
Masked by MR2	MOV HM, CR[MR2]	03A8H	Shift Comparand Right	SFT CR, R	0600H
Mask Register 1	MOV HM, MR1	0329H	Shift Comparand Left	SFT CR, L	0600H
Mask Register 2	MOV HM, MR2	032AH	Shift Mask Register 2 Right	SFT M2, R	0610H
-					
Memory at Highest-Priority Mat	ich Location set Valid	from	Shift Mask Register 2 Left Select Foreground Registers	SFT M2, L SER	0611H
Comparand Register	MOV HM,CR,V	032CH	Select Foreground Registers	SFR	0618H
Masked by MR1	MOV HM,CR[MR1],V	032CH	Select Background Registers	SBR	0619H
	MOV HM,CR[MR1],V	036CH 03ACH	Reset Seg. Cont. Reg. to Initial Val.		061AH
Masked byMR2		032DH			
Mask Register 1		10/10			
Mask Register 1 Mask Register 2			Instruction: Missollance	ue Instructions	
Mask Register 1 Mask Register 2	MOV HM,MR1,V MOV HM,MR2,V	032EH	Instruction: Miscellaneo		
-			Operation	Mnemonic	Op-Code
-					Op-Code 0300H 0700H

		CYCLETYP	E					
CYCLE LENGTH	Command Write	Command Read	Data Write	Data Read				
Short	MOV reg, reg (except L-70) TCO reg (except CT) TCO CT (non-reset, HMA invalid) SPS, SPD, SFR SBR, RSC NOP (except L-70) SFT (A)		Comparand register (not last segment) Mask register (not last segment)					
Medium	MOV reg, reg (L-70) MOV reg, mem TCO CT (reset) VBC (NFA invalid) NOP (L-70) SFT (L)	Status register or 16-bit register	Memory array (NFA invalid)	Comparand register Mask register				
Long	MOV mem, reg TCO CT (non-reset, HMA valid) CMP SFF VBC (NFA valid)		Memory array (NFA valid) Comparand register (last segment) Mask register (last segment)	Memory array				
Sect	Note: The specific timing requirements for Short, Medium, and Long cycles are given in the Switching Characteristics Section under the tELEH parameter. For two cycle Command Writes (TCO reg or any instruction with "aaaH" as the source or destination), the first cycle is short, and the second cycle will be the length given.							

INSTRUCTION SET SUMMARY Continued

Table 7: Instruction Cycle Lengths

REGISTER BIT ASSIGNMENTS

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
RST	Match	n Flag	Full	Flag	Trans	lation	CAI	M/RAM	Part.	Comp.	. Mask	AR Ir	nc/Dec	Мо	de
R E S E T = 0	=(Disa =	ange	Ena = I Disa = I No Cł =	00 able 01 nange	Input Trans = (Inp Trans = (No Ch = 1	lated)0 ut lated)1 ange	48 CAI 32 CAI 16 CAI 48 RAI 32 RAI 16 RAI	VI/32 RA VI/48 RA VI/16 CA VI/32 CA	M = 001 M = 010 M = 011 M = 100 M = 101 M = 110	MR1 MR2	= 10 nange	= Decr = Dis = No C	ement 00 ement 01 able 10 hange 11	Stand Mo Enha Mo = (Rese = 7 No Ch = 7	de)0 nced de)1 rved 10 ange
Note:	Note: D15 reads back as 0.														

Table 8: Contro	l Register E	Bit Assignments
-----------------	--------------	-----------------

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
SDL	DC	SL	DC	EL	SSL	SC	SL	SC	EL	LDC	DS	CV	LSC	SS	CV
Set Dest. Seg. Limits = 0 No Chng. = 1	Co St Lii	nation ount art mit)–11	Co E Lii	nation punt nd mit)–11	Set Source Seg. Limits = 0 No Chng. = 1	Co St	urce unt art mit I–11	Sou Coi Er Lin =00	unt nd nit	Load Dest. Seg. Count = 0 No Chng. = 1	S Co Va	ination eg. bunt alue 0–11	Load Src. Seg. Count = 0 No Chng. = 1	Sou Se Cou Val =00	g. unt ue
Note:	Note: D15, D10, D5, and D2 read back as 0s.														

REGISTER BIT ASSIGNMENTS Continued

Table 9: Segment Control Register Bit Assignments

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Page Address, PA3-0 Next Free Address, NF11-0															
	: The l imme				-			and is	access	ed by	perforr	ning a	Comma	and Re	ad

Table 10: Next Free Address Register Bit Assignments

Page Address Bits, PA 14–3							
0							
PA2-0 Match Address, AM11-0 /MA							

Table 11: Status Register Bit Assignments

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
	Device ID = 440H PS														
				ource re ving a T				and is	access	sed by	perforr	ming a	Comm	and Re	ead

Table 12: Persistent Source Register Bit Assignments

OPERATIONAL CHARACTERISTICS

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	4480A	-0.5
	4480L	-0.5
Voltage on all other	pins	-0.5
-		10 ns
Temperature under I	olas	-55°
Storage Temperatur	e	-55°
DC Output Current		20 m

-0.5 to 7.0 Volts -0.5 to 4.6 Volts -0.5 to VCC +0.5 Volts (-2 Volts for 10 ns, measured at the 50% point) -55°C to 125°C -55°C to 125°C 20 mA (per output, one at a time, one second duration. Stresses exceeding those listed under Absolute Maximum Ratings may include failure. Exposure to absolute maximum ratings for extended periods may reduce reliability. Functionality at or above these conditions is not implied.

All voltages referenced to GND.

OPERATING CONDITIONS (voltages referenced to GND at the device pin)

Symbol	Parameter		Min	Typical	Max	Units	Notes
V _{CC}	Operating Supply Voltage	4480A	4.75	5.0	5.25	Volts	
		4480L	3.0	3.3	3.6	Volts	
V _{IH}	Input Voltage Logic 1		2.0		V _{CC} + 0.5	Volts	
V _{IL}	Input Voltage Logic 0		-0.5		0.8	Volts	1, 2
ТА	Ambient Operating	Commercial	0		70	°C	Still Air
	Temperature	Industrial	-40		85	°C	

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter		Min	Typical	Max	Units	Notes
С С	Average Power Supply Current	4480A		135	200	mA	t _{ELEL =} t _{ELEL(min);} 9
		4480L		85	160	mA	· · //
I _{CC(SB)}	Stand-by Power Supply Current	4480A			7	mA	/E = HIGH
		4480L			2	mA	
V _{OH}	Output Voltage Logic 1		2.4			Volts	I _{OH} = -2.0mA
V _{OL}	Output Voltage Logic 0				0.4	Volts	I _{OL} = 4.0mA
Ι _{IZ}	Input Leakage Current	Others	-2		+2	μA	$V_{SS} \leq V_{IN} \leq V_{CC}$
		/RESET	6	9	12	Kohms	$V_{IN} = 0 V$
		TEST1,TEST2	6	10	13		V _{IN} = V _{CC} ; 10
loz	Output Leakage Current		-10		10	μA	$V_{SS} \le V_{OUT} \le V_{CC};$
							$DQ_N = High Impedance$

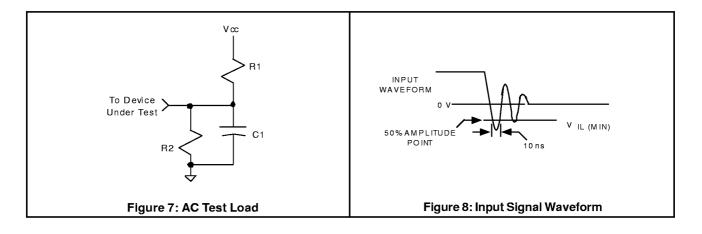
CAPACITANCE

Symbol	Parameter	Max	Units	Notes
C _{IN}	Input Capacitance	6	pF	f = 1 MHz, V _{IN} = 0 V
COUT	Output Capacitance	7	pF	f = 1 MHz, V _{OUT} = 0 V

AC TEST CONDITIONS

Input Signal Transitions	0.0 Volts to 3.0 Volts
Input Signal Rise Time	< 3 ns
Input Signal Fall Time	< 3 ns
Input Timing Reference Level	1.5 Volts
Output Timing Reference Level	1.5 Volts

SWITCHING TEST FIGURES



SWITCHING TEST FIGURES COMPONENT VALUES

Parameter		4480 A	4480L	Units
VCC		5.0	3.3	Volts
R1		961	635	Ohms
R2		510	702	Ohms
C1 (includes jig)	Test Load A	30	30	pF
	Test Load B	5	5	pF

	Available	9	Cycle Time	-7	70	-	90	-1	2	1
	• • Consult	factory for availability	4480A		•		•		•	
			4480L		•		•		•	
No	Symbol	Parameter (all times in nanos	econds)	Min	Max	Min	Max	Min	Max	Notes
1	^t ELEL	Chip Enable Compare Cycle T	me	70		90		120		
2	^t ELEH	Chip Enable LOW Pulse Width	Short Cycle:	15		25		35		4
			Medium Cycle:	35		50		75		4
			Long Cycle:	55		75		100		4
3	^t EHEL	Chip Enable HIGH Pulse Width		15		15		20		
4	^t CVEL	Control Input to Chip Enable LC	W Set-up Time	0		0		0		5
5	^t ELCX	Control Input from Chip Enable	LOW Hold Time	10		10		15		5
6	^t elqx	Chip Enable LOW to Outputs Ac	ctive	3		3		3		6
7	^t elqv	Chip Enable LOW to Outputs V	alid		30		50		70	4,6
					52		75		85	4,6
8	^t ehqz	Chip Enable HIGH to Outputs H	ligh-Z	3	10	3	15	3	20	7
9	^t DVEL	Data to Chip Enable LOW Set-	up Time	0		0		0		
10	^t ELDX	Data from Chip Enable LOW H	old Time	10		10		15		
11	^t FIVEL	Full In Valid to Chip Enable LO	V Set-up Time	0		0		0		
12	[‡] FIVFFV	Full In Valid to Full Flag Valid			5		7		8	
13	^t elffv	Chip Enable LOW to Full Flag \	/alid		50		75		90	
14	^t MIVEL	Match in Valid to Chip Enable L	OW Set-up Time	0		0		0		
15	^t EHMFX	Chip Enable HIGH to /MF, /MA, /	MM Invalid	0		0		0		
16	^t MIVMFV	Match In Valid to /MF, /MA, /MM V	'alid		5		7		8	
17	^t ehmfv	Chip Enable HIGH to /MF Valid			16		25		30	
18	^t EHMXV	Chip Enable HIGH to /MA and /M	/IM Valid		18		25		30	
19	^t RLRH	Reset LOW Pulse Width		100		100		100		8

Notes:

1. -1.0V for a duration of 10 ns measured at the 50% amplitude points for Input-only lines (Figure 8).

2. Common I/O lines are clamped, so that signal transients cannot fall below -0.5V.

3. Over ambient operating temperature and Vcc(min) to Vcc(max).

4. See Table 7 on page 20.

5. Control signals are /W, /CM, and /EC.

6. With load specified in Figure 7, Test Load A.

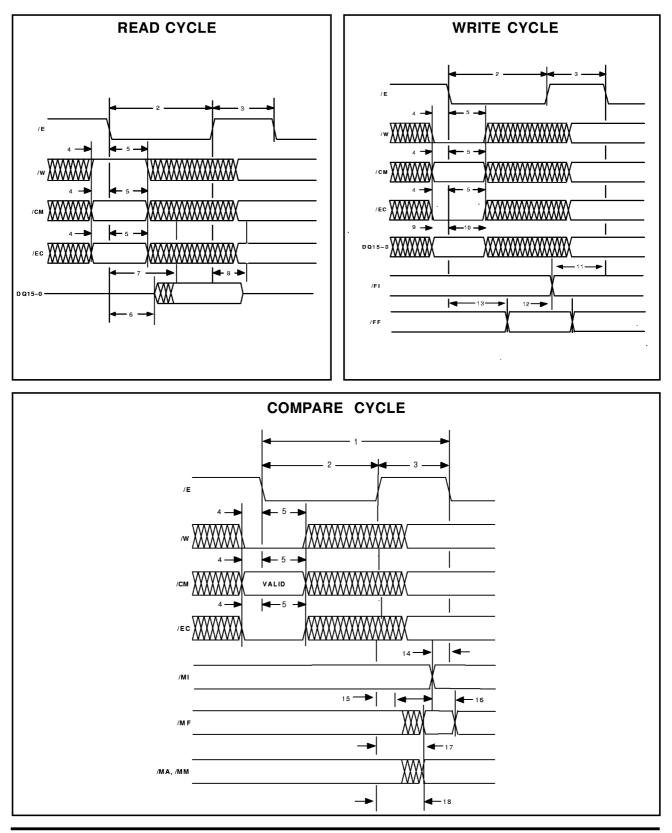
7. With load specified in Figure 7, Test Load B.

8. /E must be HIGH during this period to ensure accurate default values in the configuration registers.

9. With output and I/O pins unloaded.

10. TEST1 and TEST2 may not be implemented on all versions of these products.



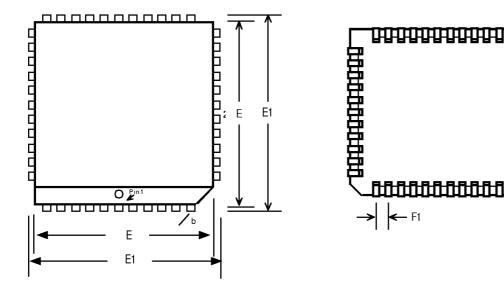


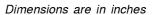
NOTES

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PACKAGE OUTLINE



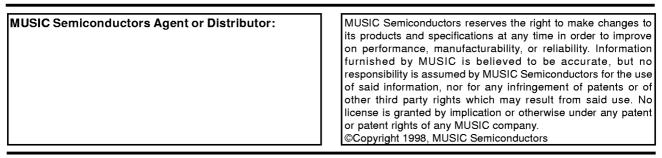


a **

	Dim. A	Dim. B	Dim. C	Dim. D	Dim. E	Dim. E1	Dim. F	Dim. F1	Dim. a	Dim. b
44-pin	.170	.017	.018	.100	.650	.685	.590	.05	3°	43 °
PLCC	.180	ТҮР	.032	ТҮР	.656	.695	.630	ТҮР	6 °	47

Part Number	Cycle Time	Package	Temperature	Voltage
MU9C4480A - 70DC	70ns	44-PIN PLCC	0–70° C	5.0 ± 0.25
MU9C4480A - 90DC	90ns	44-PIN PLCC	0–70° C	5.0 ± 0.25
MU9C4480A - 12DC	120ns	44-PIN PLCC	0–70° C	5.0 ± 0.25
MU9C4480L - 70DC	70ns	44-PIN PLCC	0–70° C	3.3 ± 0.3
MU9C4480L - 90DC	90ns	44-PIN PLCC	0–70° C	3.3 ± 0.3
MU9C4480L - 12DC	120ns	44-PIN PLCC	0–70° C	3.3 ± 0.3
MU9C4480A - 70DI	70ns	44-PIN PLCC	-40–85° C	5.0 ± 0.25
MU9C4480A - 90DI	90ns	44-PIN PLCC	-40–85° C	5.0 ± 0.25
MU9C4480A - 12DI	120ns	44-PIN PLCC	-40–85° C	5.0 ± 0.25
MU9C4480L - 90DI	90ns	44-PIN PLCC	-40–85° C	3.3 ± 0.3
MU9C4480L - 12DI	120ns	44-PIN PLCC	-40–85° C	3.3 ± 0.3

ORDERING INFORMATION





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